



北京大学
PEKING UNIVERSITY

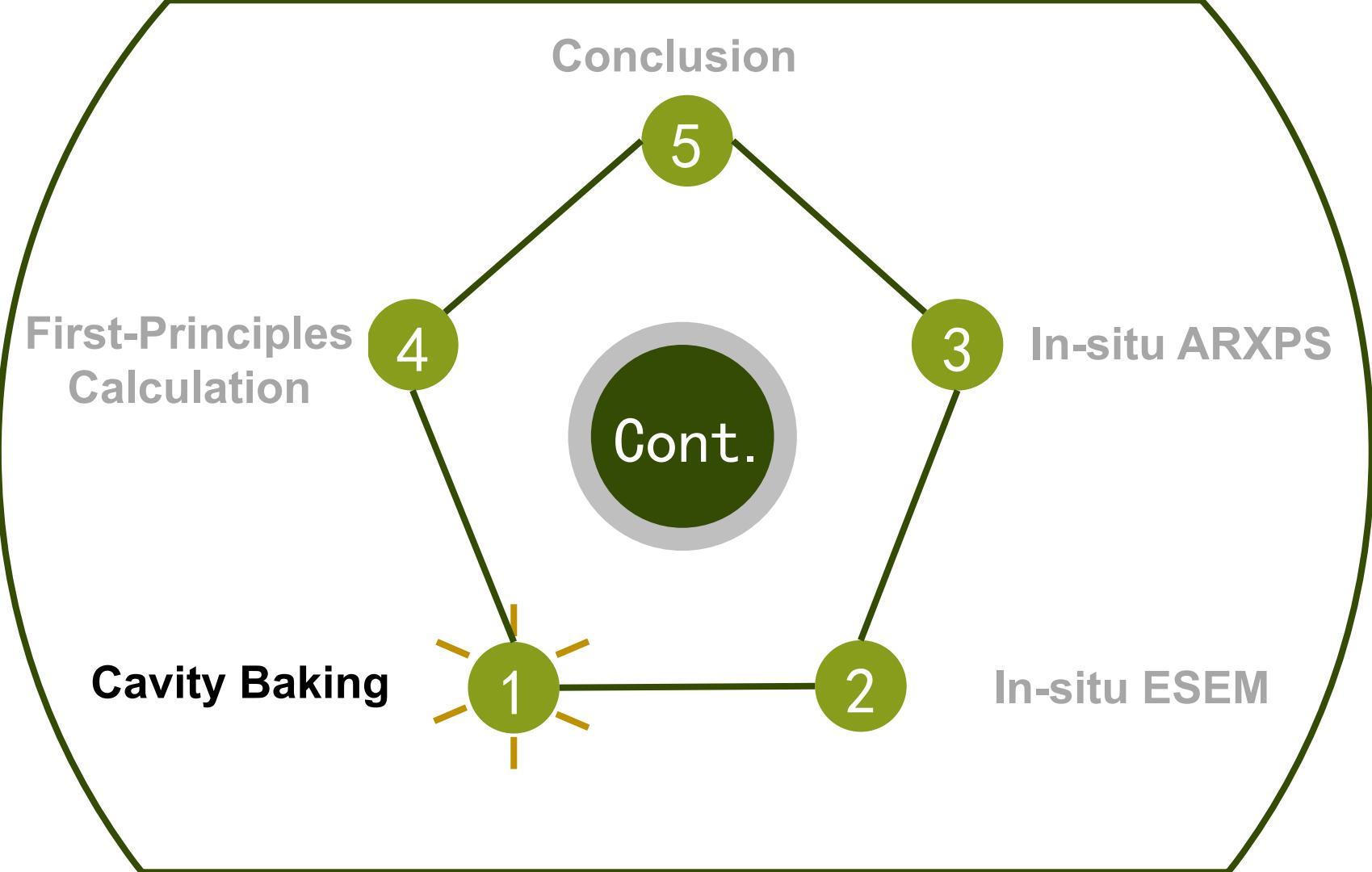


WEIAA02

Temperature Responses of Superconducting Niobium Properties in Experiment and Simulation

Presenter: Zhitao Yang
Advisor: Jiankui Hao
On behalf of PKU SRF team

2023.06.28



1.1

Baking Temperature



3

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a 75-100°C

- 4 h - Pre-Baking
- Improve max E_{acc} effectively



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b 120-180°C

- 48 h - Low Temperature Baking
- Suppress HFQS effectively
- 48 h - Nitrogen Infusion
- Improve Q_0

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c 300-400°C

- 1-3 h - Medium Temperature Baking
- High Q_0 and Acceptable E_{acc}



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- 1-3 h - Medium Temperature Baking
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d 800-900°C

- 3 h - High Temperature Annealing
- Hydrogen degassing and Recrystallization
- 2/0, 2/6, 10/20, 20/30, 3/60, Nitrogen Doping
- Improve Q_0

1.2

Cavity Performance

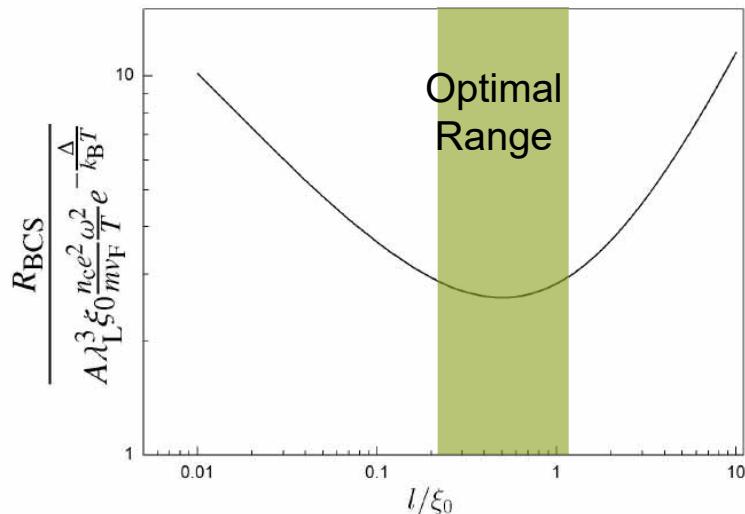
Medium Temperature Baking



1980

Cornell
F.
Palmer

8.6 GHz Nb cavity, 250-300°C 5-10 min, $R_{BCS} \downarrow$ 10-20%;
350°C 10 min, $R_{res} \downarrow$;
Nb-O compounds \downarrow , Interstitial O \uparrow , MFP Opt



4

Cavity Performance

Medium Temperature Baking



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2008

Jlab
G.V.Eremeev

1.5 GHz Nb Cavity, 400°C 1 h, HFQS, high R_{res} ,
Nb-O compounds $\downarrow \uparrow$, Non-stoichiometric Nb-O,
Interstitial O not enough;

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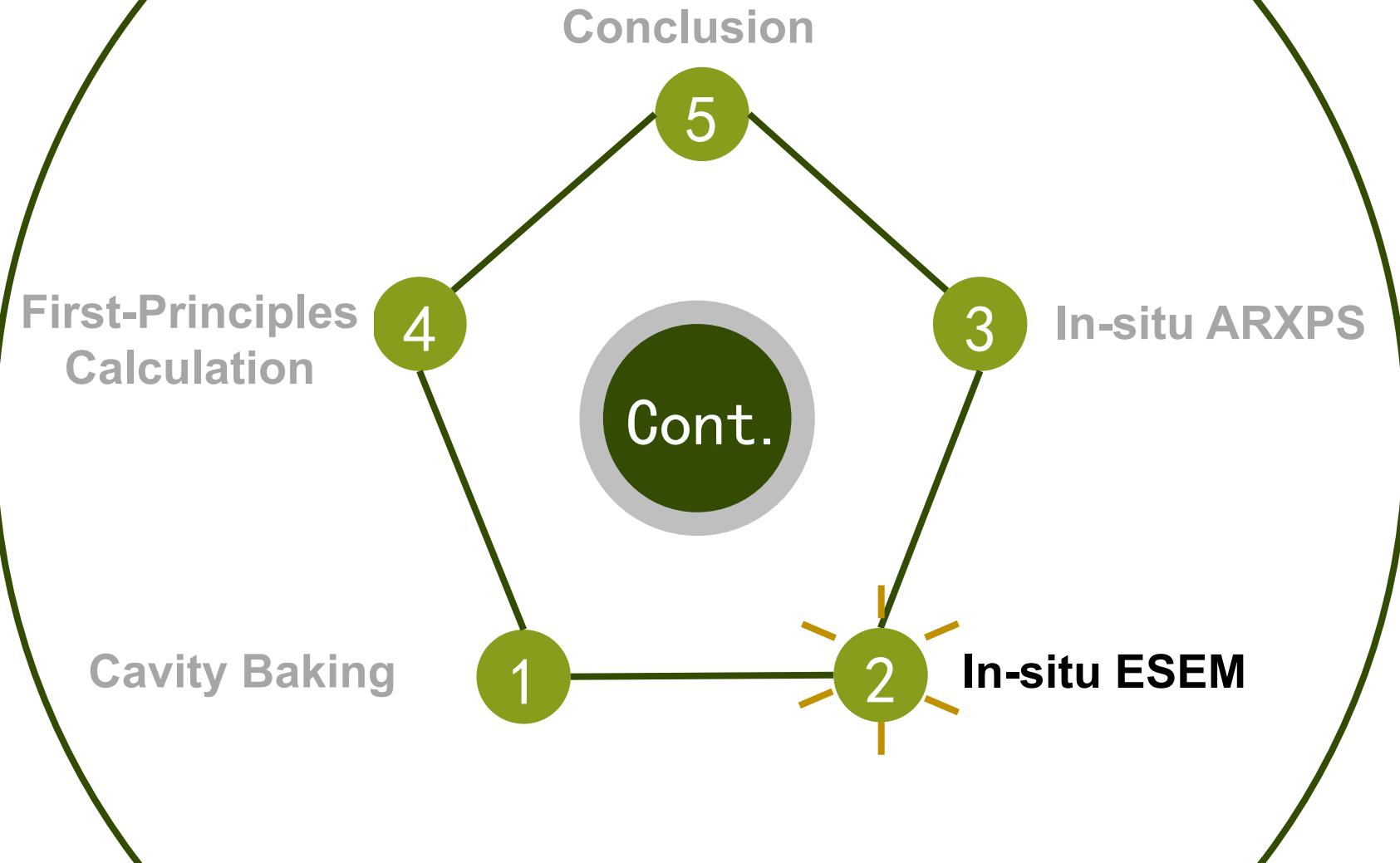
Jlab
G.V.Eremeev

1.5 GHz Nb Cavity, 400°C 1 h, HFQS, high R_{res} ,
Nb-O compounds $\downarrow \uparrow$, Non-stoichiometric Nb-O,
Interstitial O not enough;

2020

FNAL
S. Posen

1.3 GHz Nb Cavity, 250-400°C 2.5 h, $R_{BCS} \downarrow$, $R_{res} \downarrow$;
KEK, IHEP, repetitious results;
Nb-O compounds \downarrow , Interstitial O & N \uparrow , MFP Opt;



Introduction of in-situ ESEM



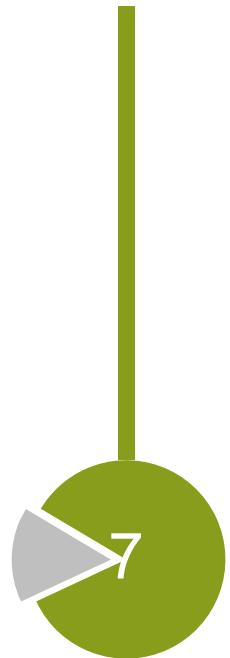
- Heavily chemically polished baseline samples
- In-situ environmental scanning electron spectroscopy (ESEM)
- Liquid nitrogen cooling platform



- Observation while cooling and heating
- First round of cooling: precipitation and scars
- Second round of cooling: repeatable scars and precipitation

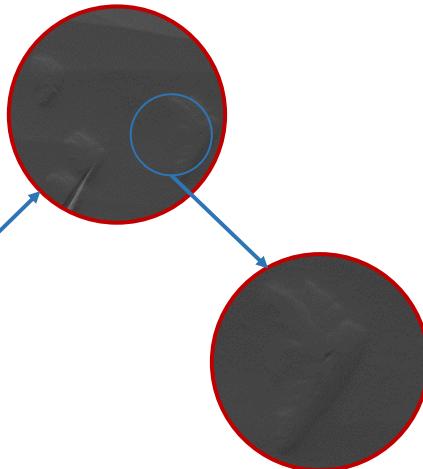
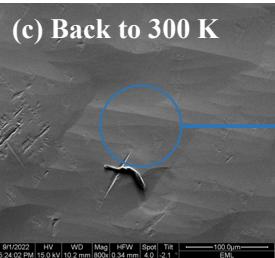
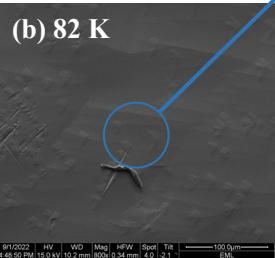
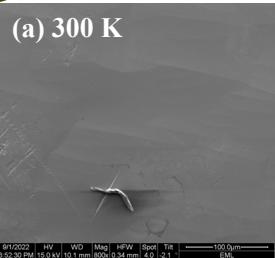
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Nb-H precipitation Observation



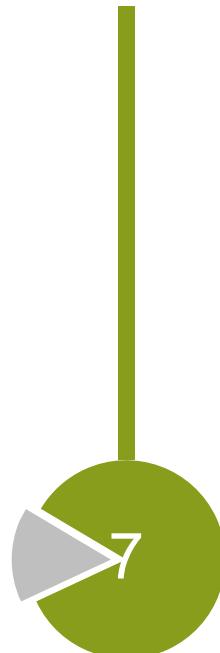
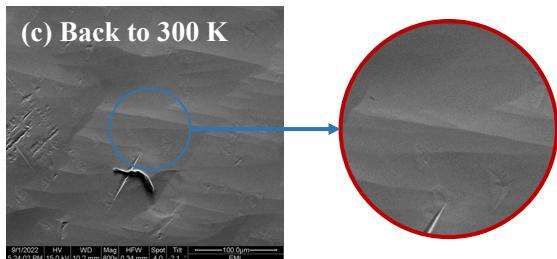
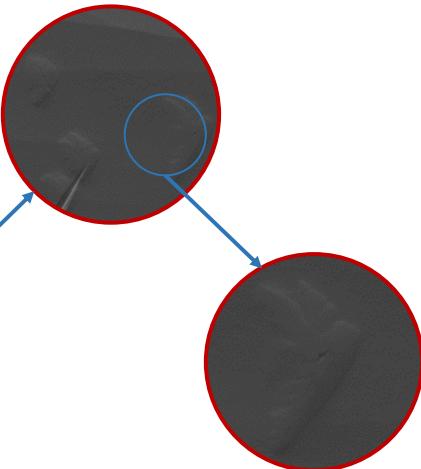
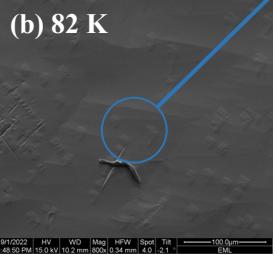
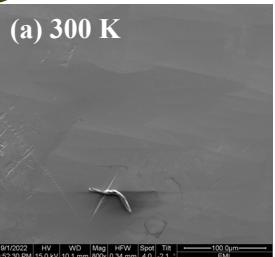
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Nb-H precipitation Observation



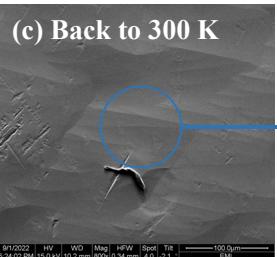
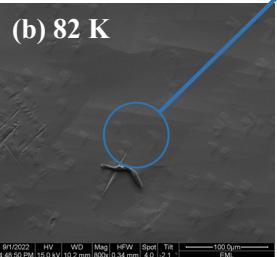
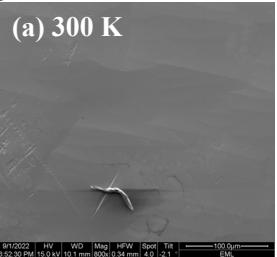
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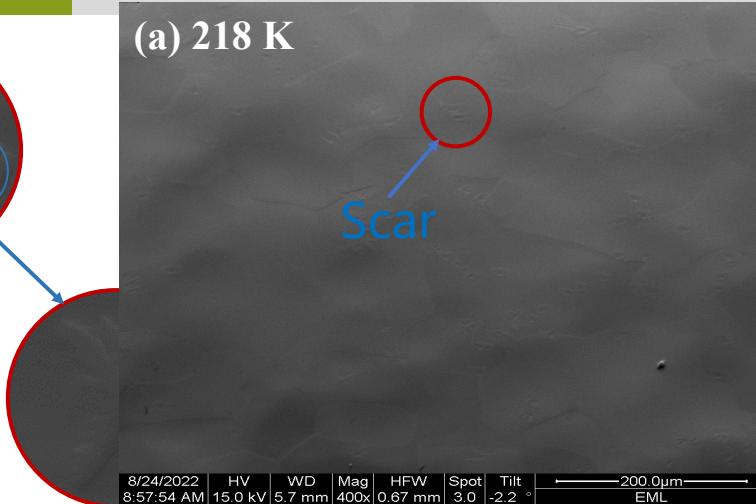


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Nb-H precipitation Observation



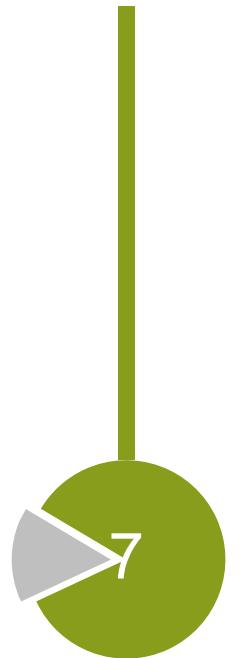
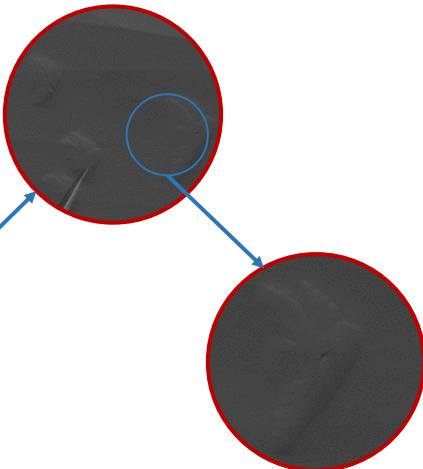
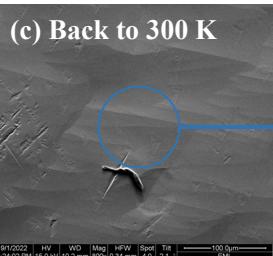
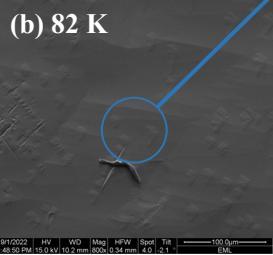
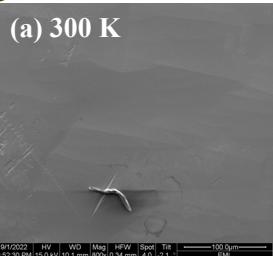
(a) 218 K



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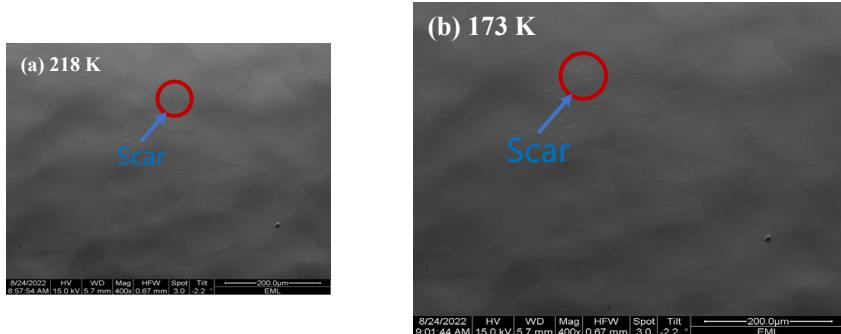
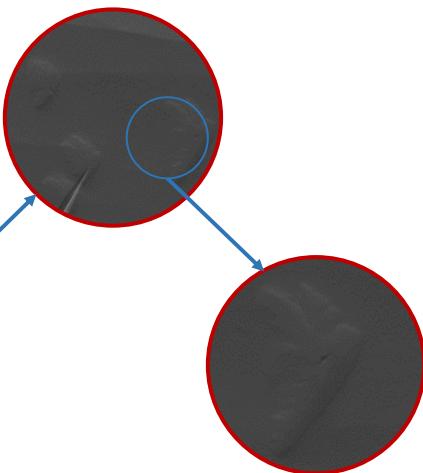
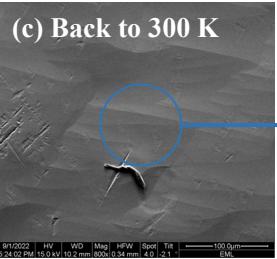
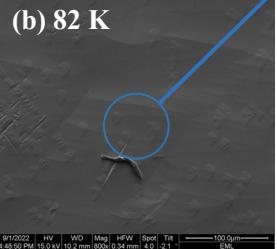
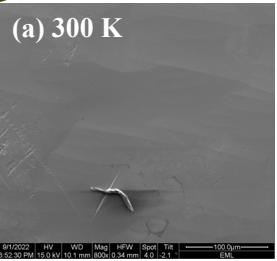
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Nb-H precipitation Observation



2.2

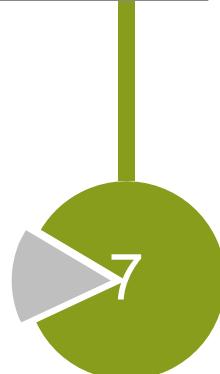
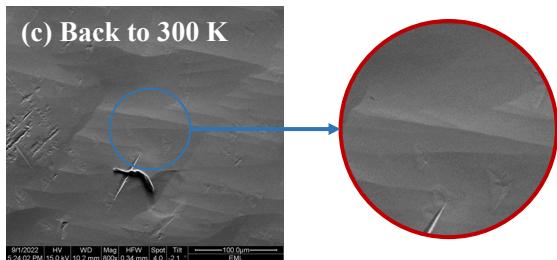
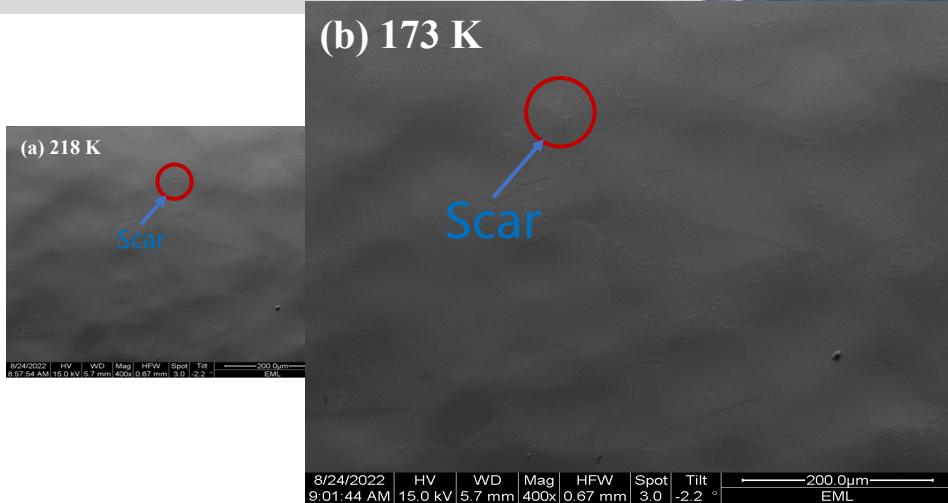
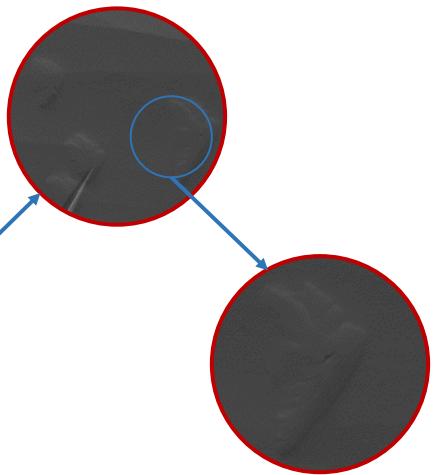
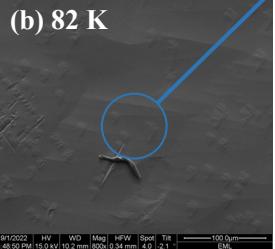
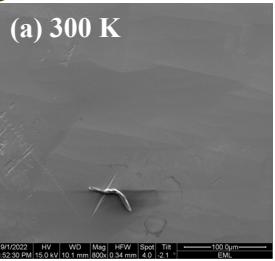
Nb-H precipitation Observation



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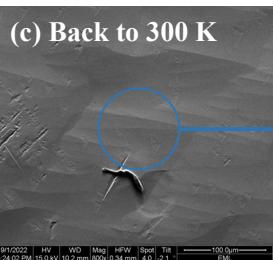
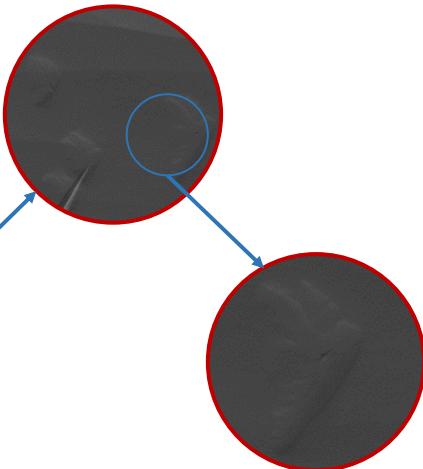
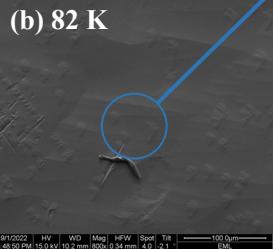
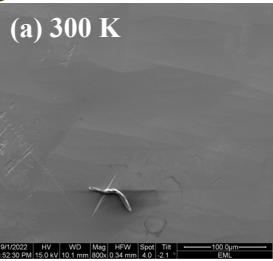
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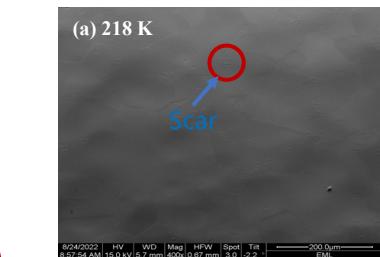
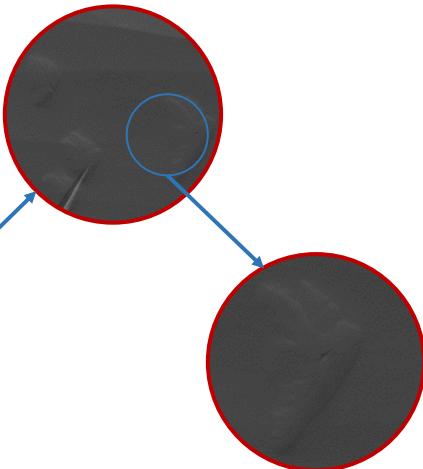
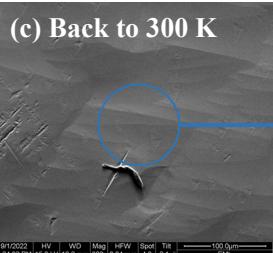
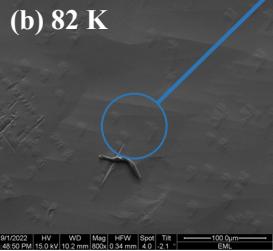
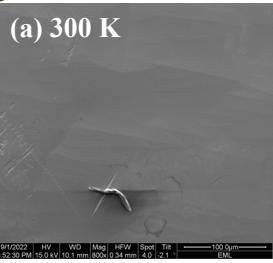
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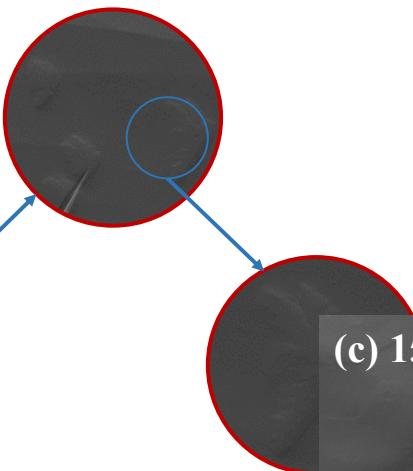
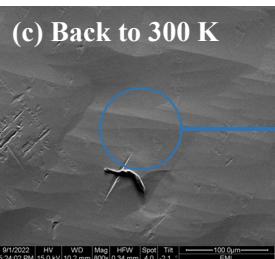
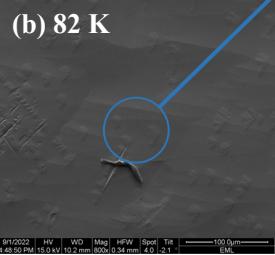
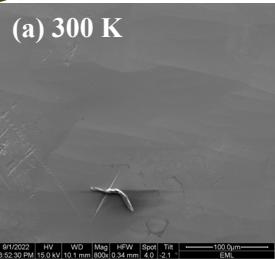
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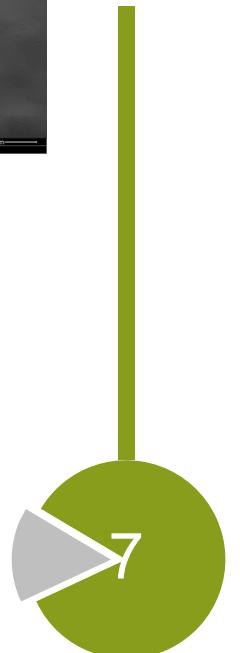
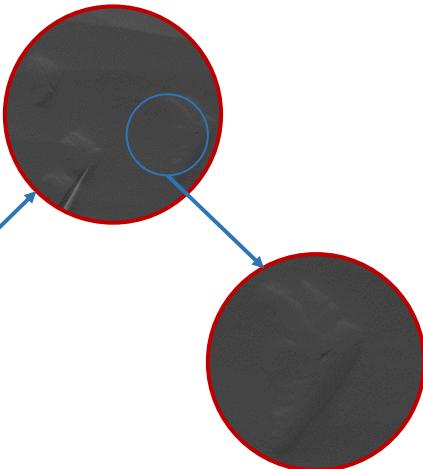
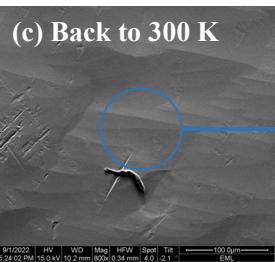
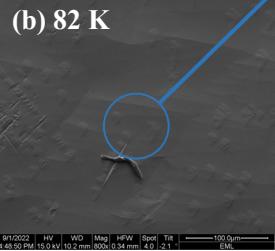
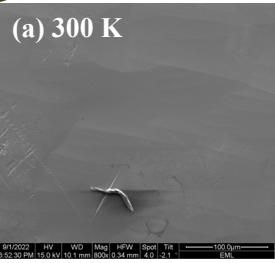
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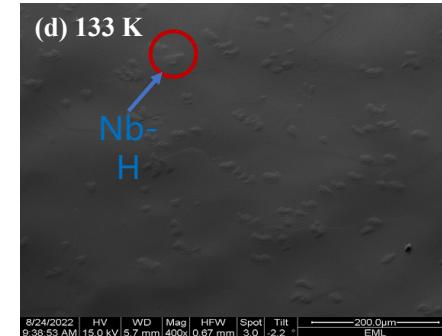
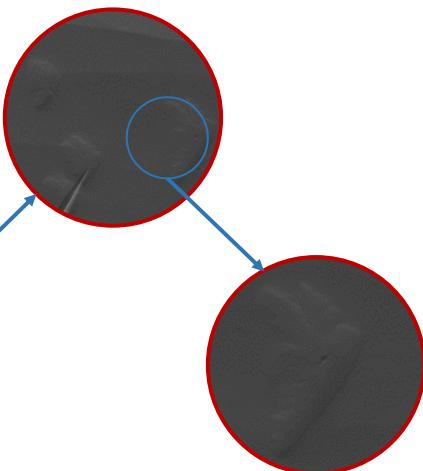
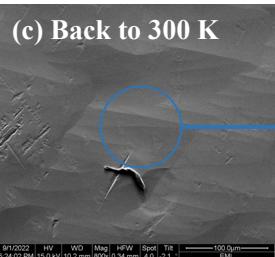
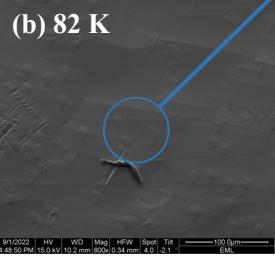
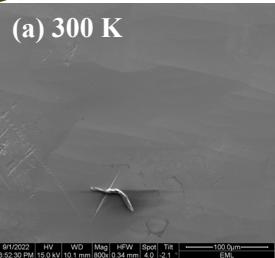
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Nb-H precipitation Observation



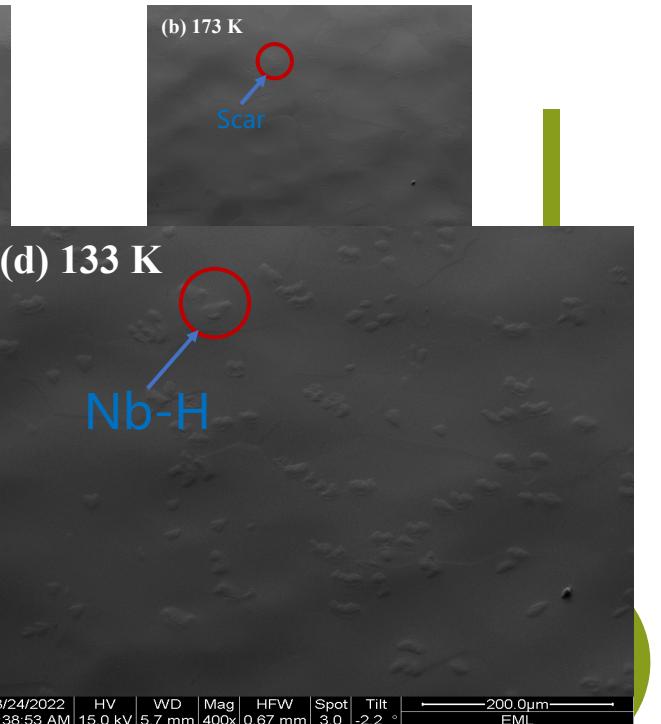
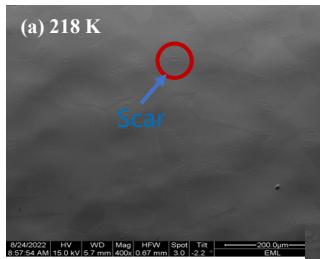
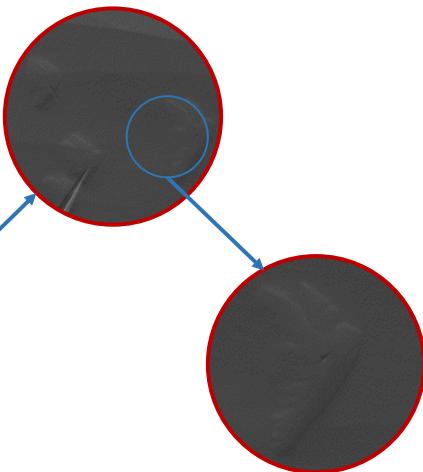
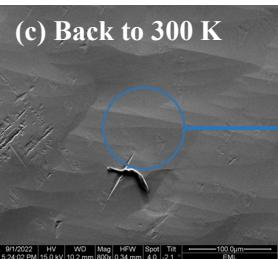
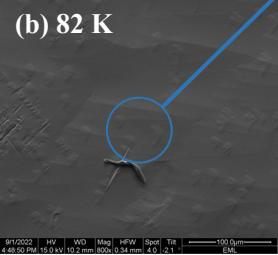
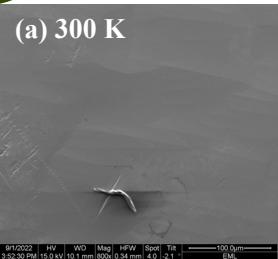
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Nb-H precipitation Observation



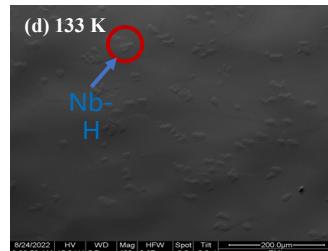
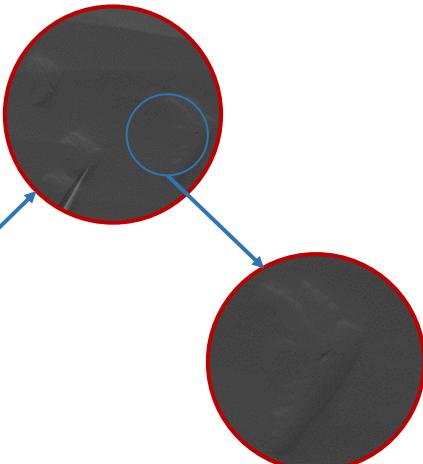
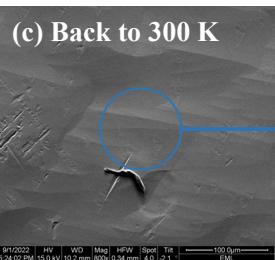
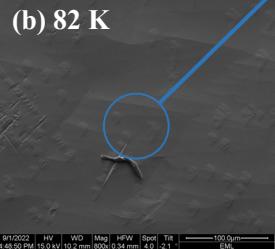
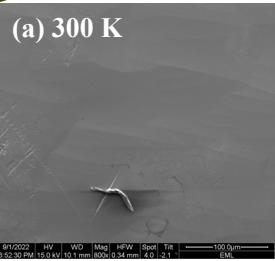
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Nb-H precipitation Observation



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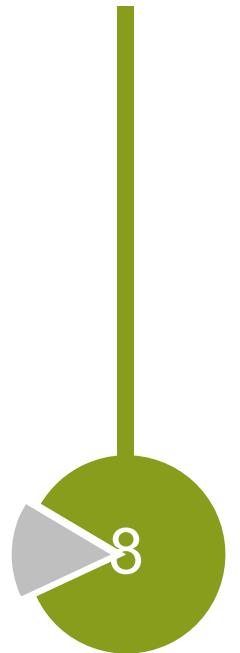
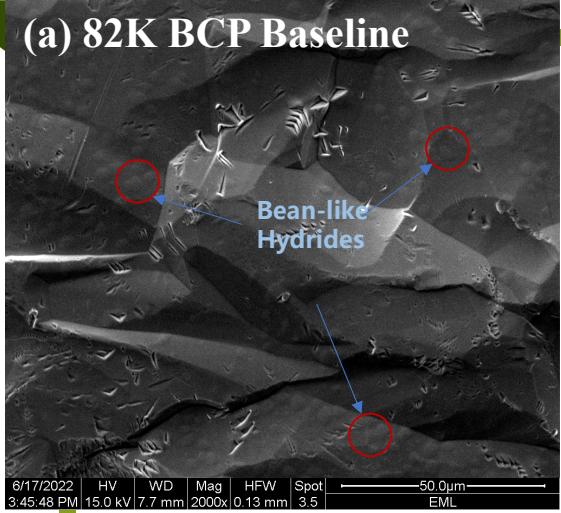
Nb-H precipitation Observation



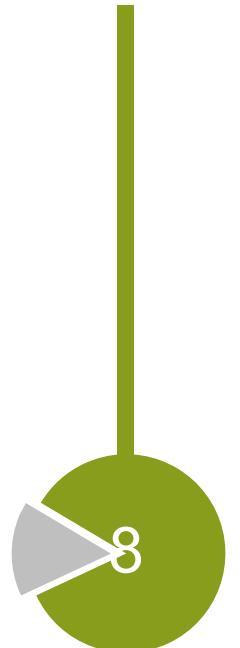
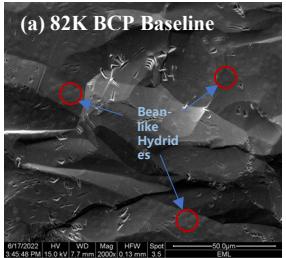
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2.3

Comparisons among baked samples



Comparisons among baked samples

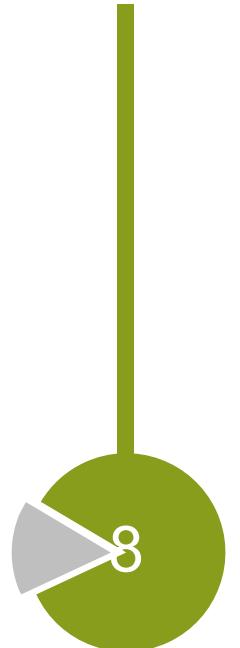
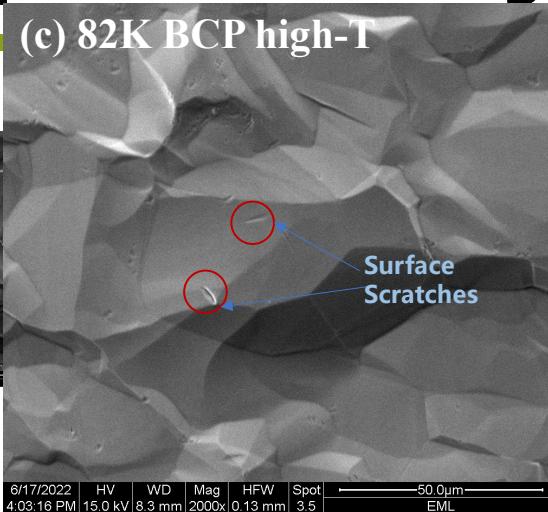
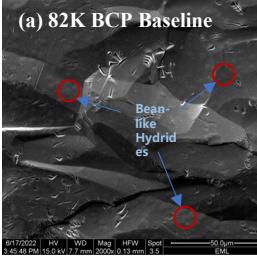


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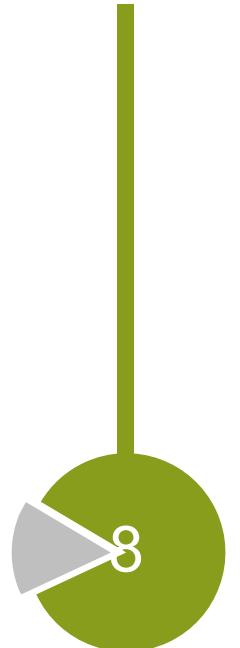
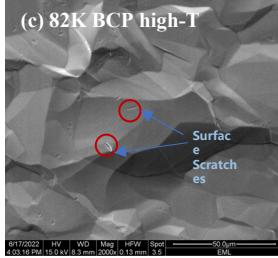
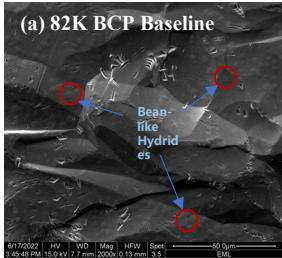
Comparisons among baked samples



(c) 82K BCP high-T

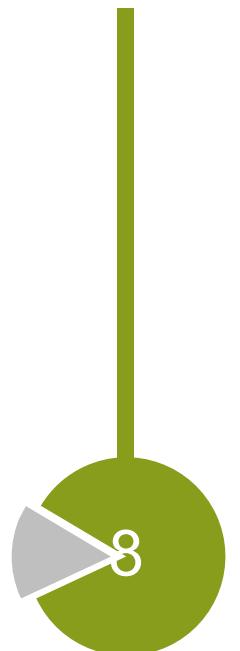
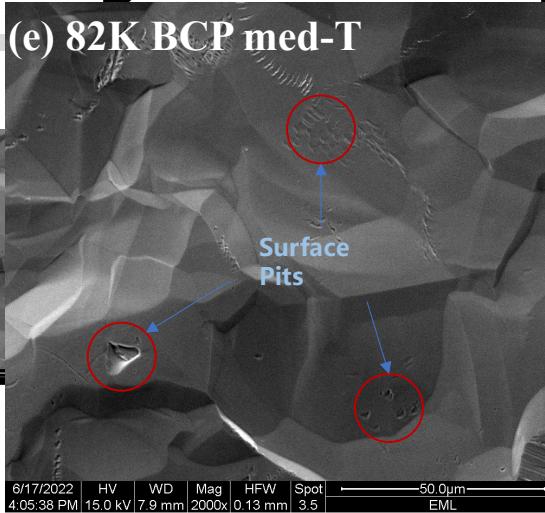
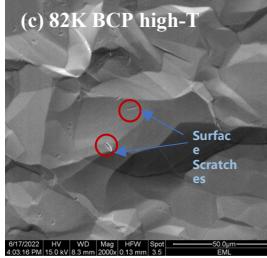
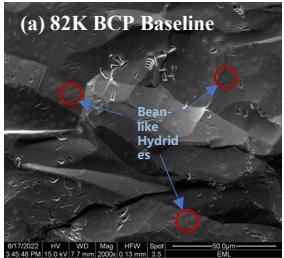


Comparisons among baked samples

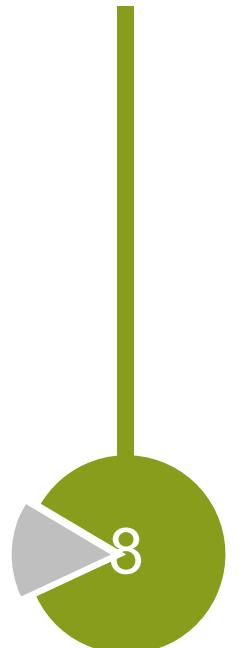
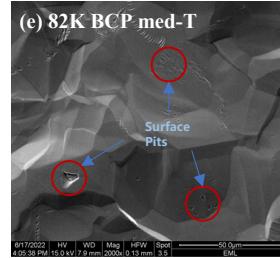
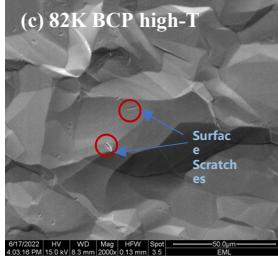


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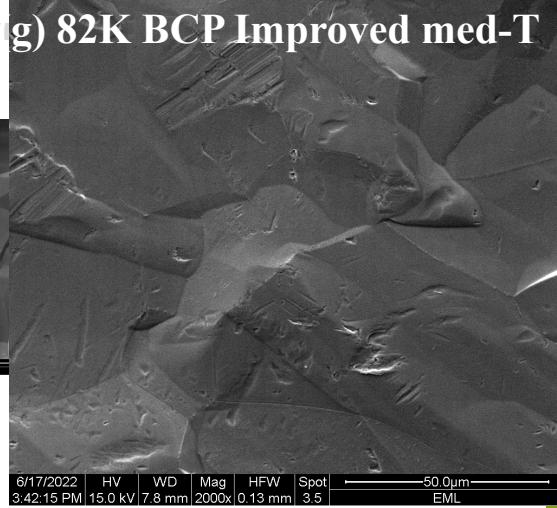
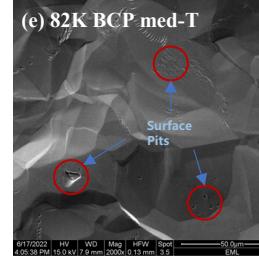
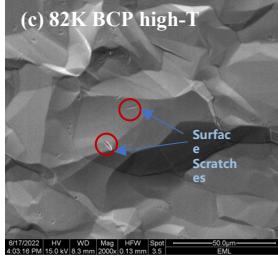
Comparisons among baked samples



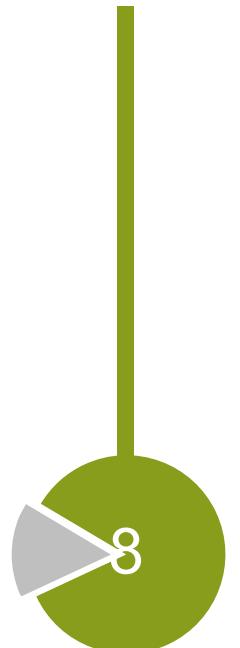
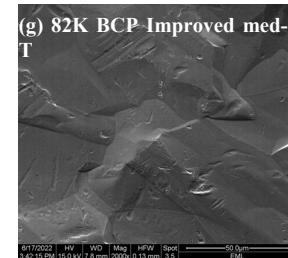
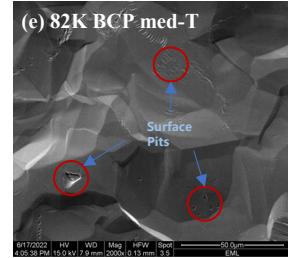
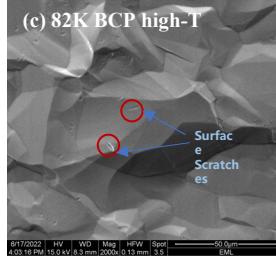
Comparisons among baked samples



Comparisons among baked samples

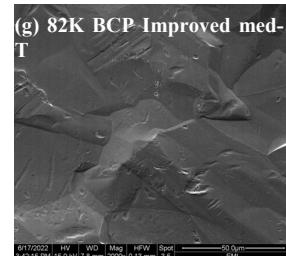
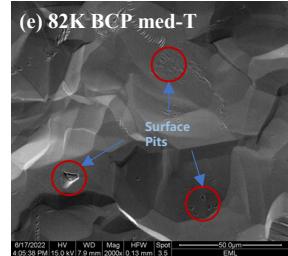
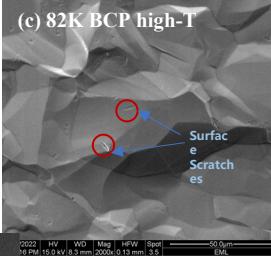


Comparisons among baked samples

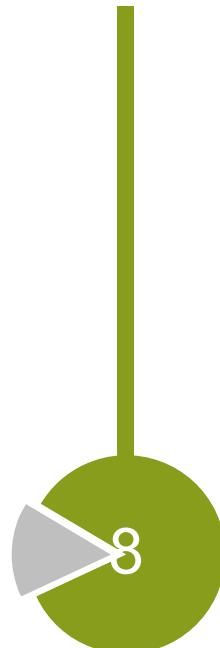
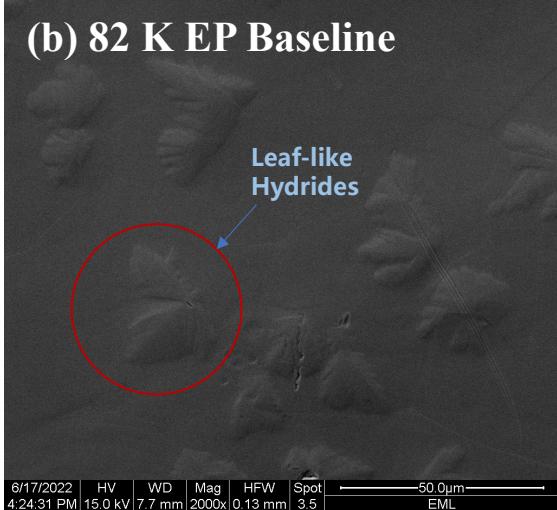


2.3

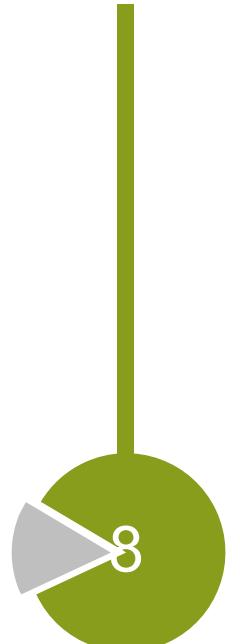
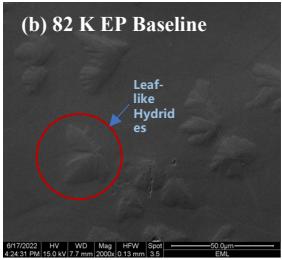
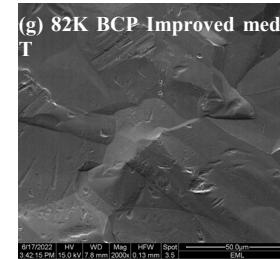
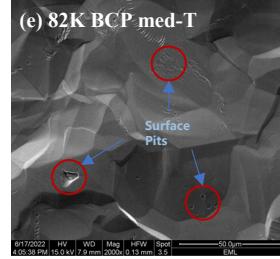
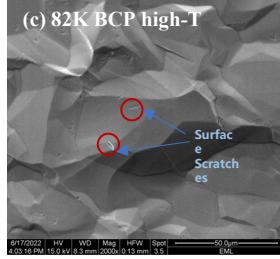
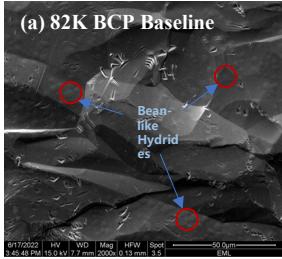
Comparisons among baked samples



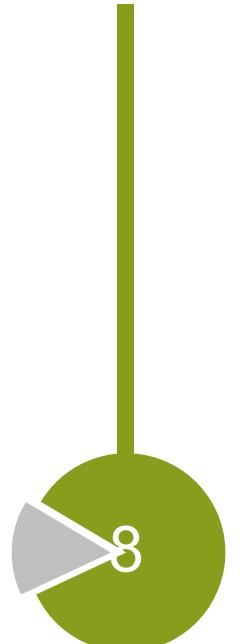
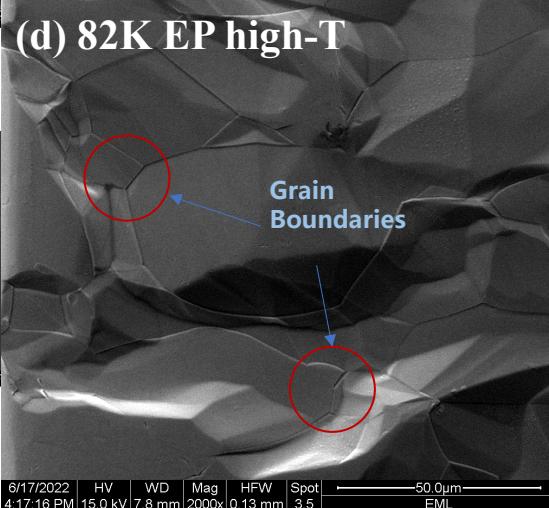
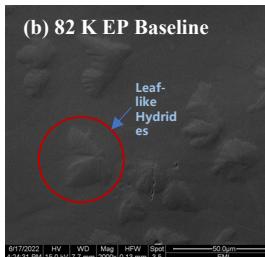
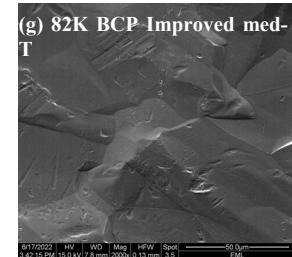
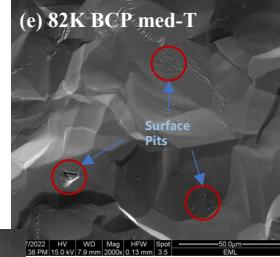
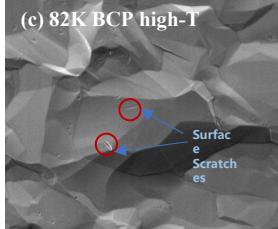
(b) 82 K EP Baseline



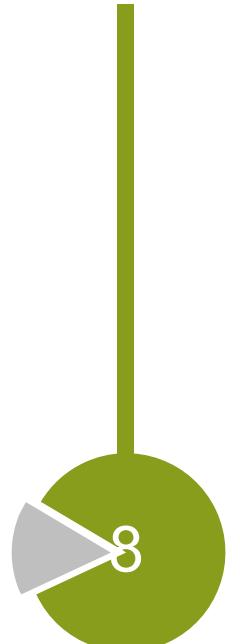
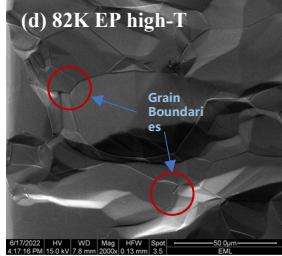
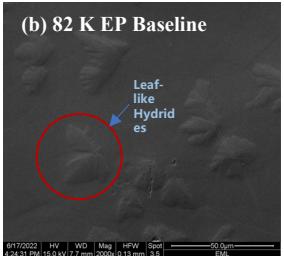
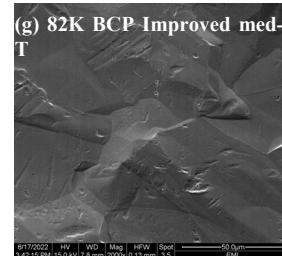
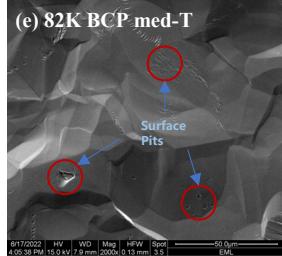
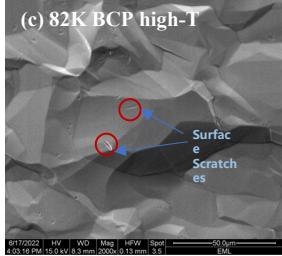
Comparisons among baked samples



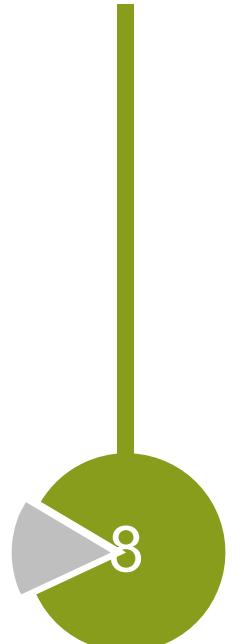
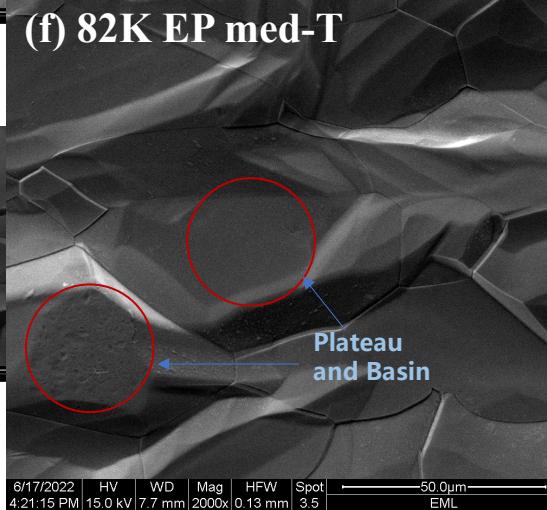
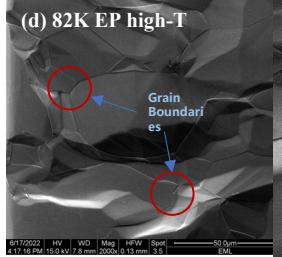
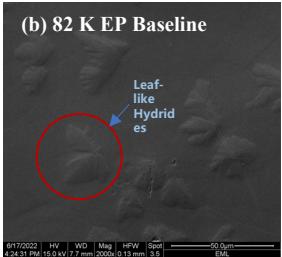
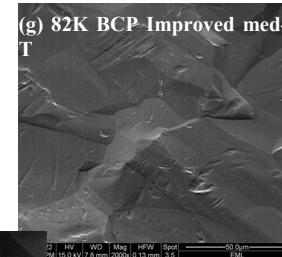
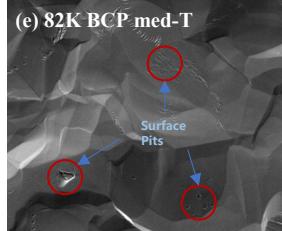
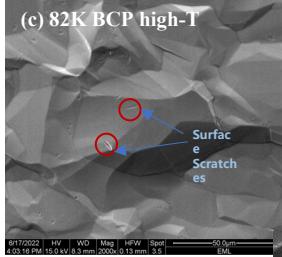
Comparisons among baked samples



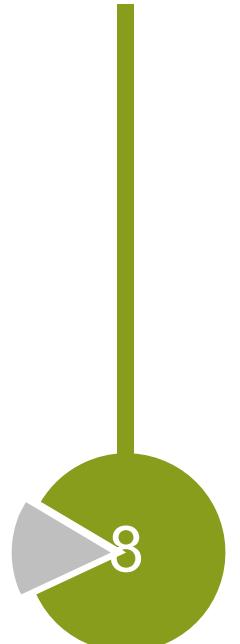
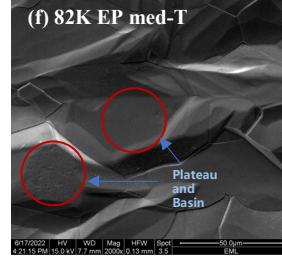
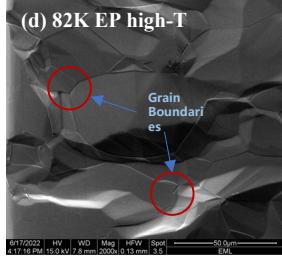
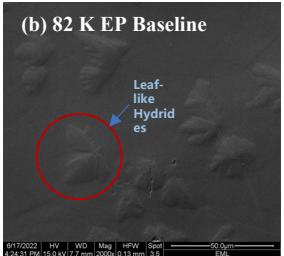
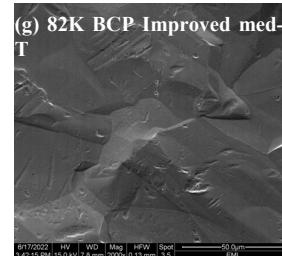
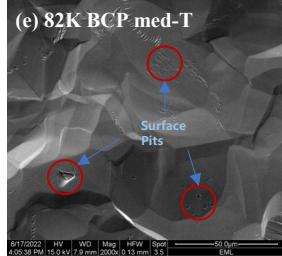
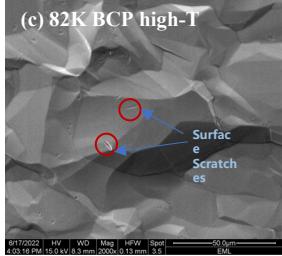
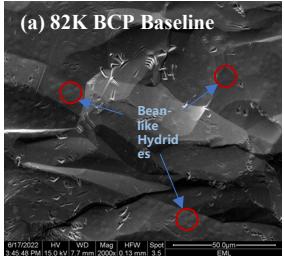
Comparisons among baked samples



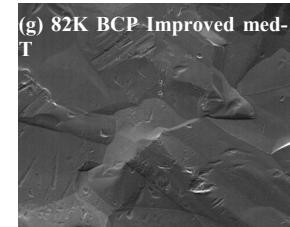
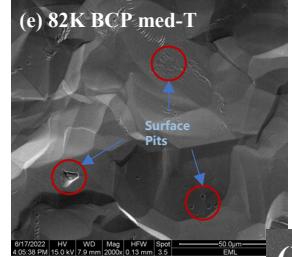
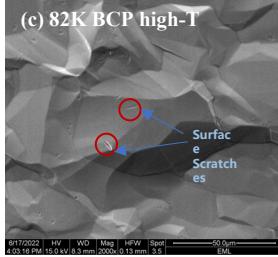
Comparisons among baked samples



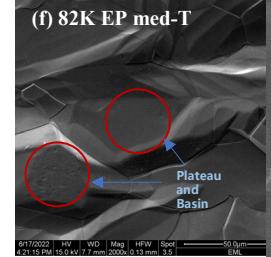
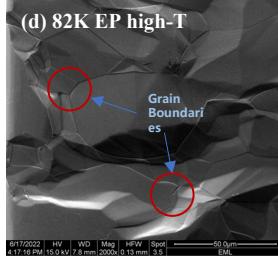
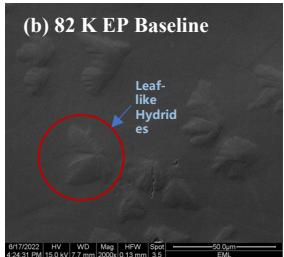
Comparisons among baked samples



Comparisons among baked samples

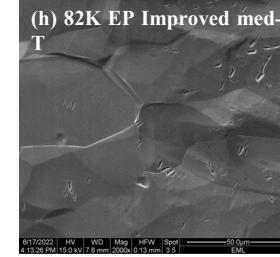
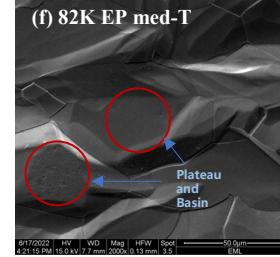
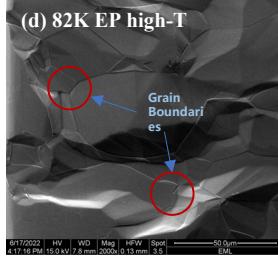
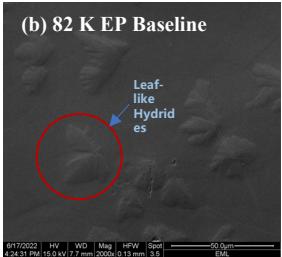
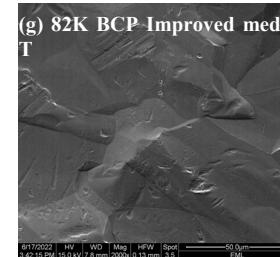
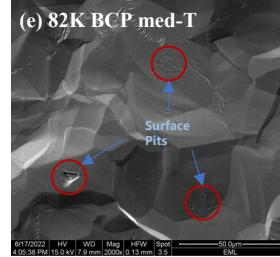
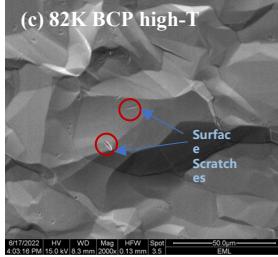


(h) 82K EP Improved med-T

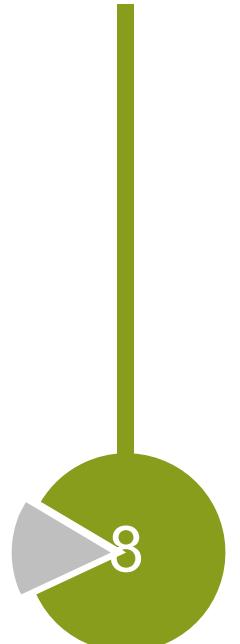


6/17/2022 HV WD Mag HFW Spot 50.0µm EML
4:13:26 PM 15.0 kV 7.8 mm 2000x 0.13 mm 3.5

Comparisons among baked samples



High-T, Medium-T, and Improved med-T can reduce Nb-H effectively

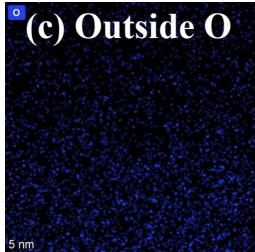
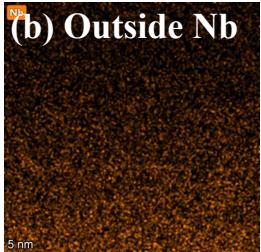
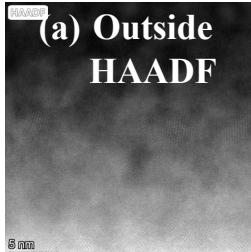


2.4

Cross section



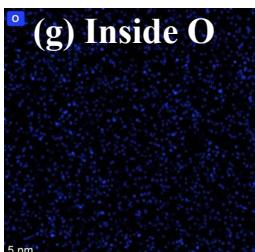
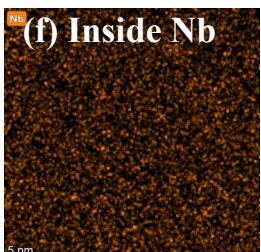
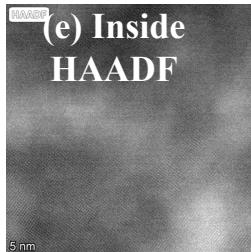
Baseline Nb sample



2022-11-02 09:46:18 Analysis of spectrum: Spectra from Area #1

(d) Outside EDS

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	K	67.78	8.12	33.23	2.71	3.25
8	O	K	17.65	4.08	11.53	2.46	0.57
41	Nb	K	14.57	2.50	55.25	8.16	0.57



2022-11-02 09:45:18 Analysis of spectrum: Spectra from Area #1

(h) Inside EDS

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	K	0.00	0.24	0.00	0.03	0.00
8	O	K	8.27	2.42	1.53	0.36	1.29
41	Nb	K	91.73	22.76	98.47	17.59	0.11

9

2.4

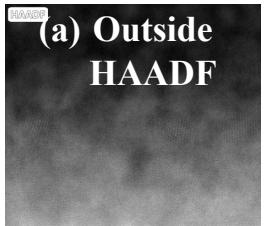
Cross section



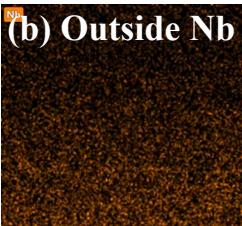
Baseline Nb sample



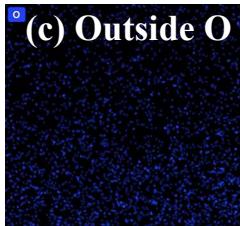
(a) Outside
HAADF



(b) Outside Nb



(c) Outside O



2022-11-02 09:46:18 Analysis of spectrum: Spectra from Area #1

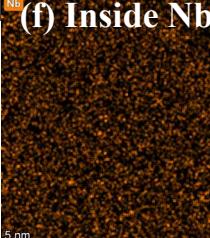
(d) Outside EDS

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	K	67.78	8.12	33.23	2.71	3.25
8	O	K	17.65	4.08	11.53	2.46	0.57
41	Nb	K	14.57	2.50	55.25	8.16	0.57

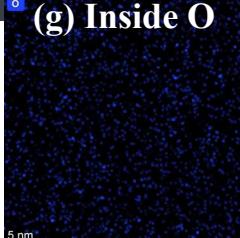
(e) Inside
HAADF



(f) Inside Nb



(g) Inside O



2022-11-02 09:45:18 Analysis of spectrum: Spectra from Area #2

(h) Inside EDS

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	K	0.00	0.24	0.00	0.03	0.00
8	O	K	8.27	2.42	1.53	0.36	1.29
41	Nb	K	91.73	22.76	98.47	17.59	0.11

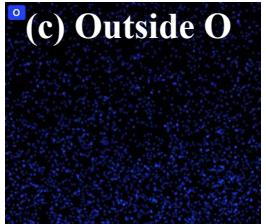
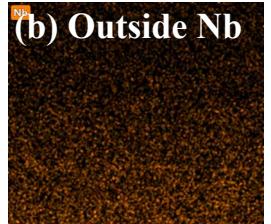
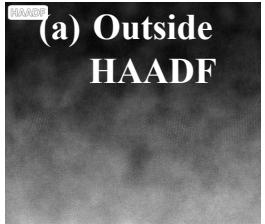
9

2.4

Cross section



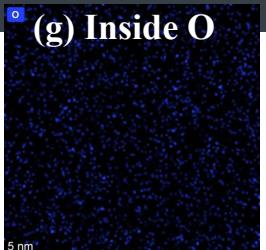
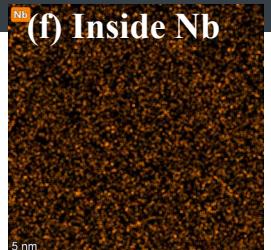
Baseline Nb sample



2022-11-02 09:46:18 Analysis of spectrum: Spectra from Area #1

(d) Outside EDS

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	K	67.78	8.12	33.23	2.71	3.25
8	O	K	17.65	4.08	11.53	2.46	0.57
41	Nb	K	14.57	2.50	55.25	8.16	0.57



2022-11-02 09:45:18 Analysis of spectrum: Spectra from Area #2

(h) Inside EDS

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	K	0.00	0.24	0.00	0.03	0.00
8	O	K	8.27	2.42	1.53	0.36	1.29
41	Nb	K	91.73	22.76	98.47	17.59	0.11

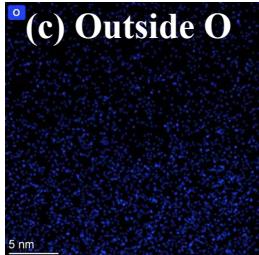
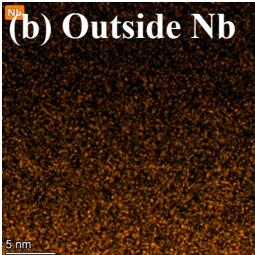
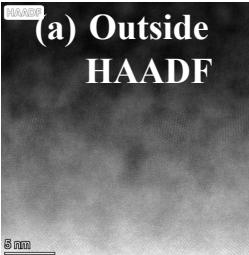
9

2.4

Cross section



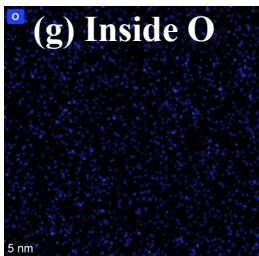
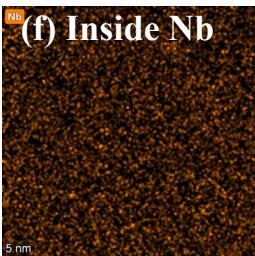
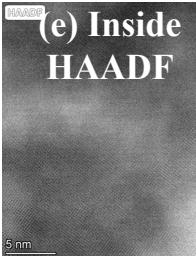
Baseline Nb sample



(d) Outside EDS

2022-11-02 09:46:18 Analysis of spectrum: Spectra from Area #1

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	[K]	17.78	8.12	33.32	3.71	3.25
8	O	[K]	17.65	4.08	11.53	2.46	0.57
41	Nb	[K]	44.57	2.50	55.25	8.16	0.57



(h) Inside EDS

2022-11-02 09:45:18 Analysis of spectrum: Spectra from Area #1

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	[K]	0.00	0.24	0.00	0.03	0.00
8	O	[K]	8.27	2.42	1.53	0.36	1.29
41	Nb	[K]	91.73	22.76	98.47	17.59	0.11

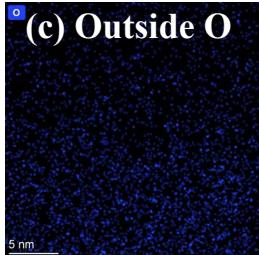
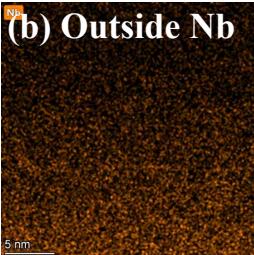
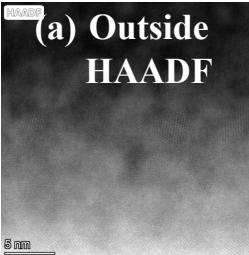
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2.4

Cross section



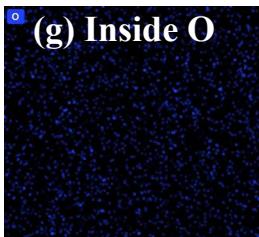
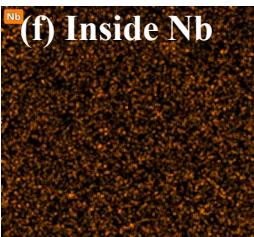
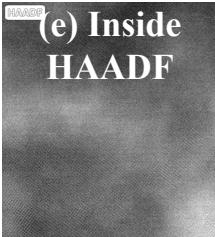
Baseline Nb sample



(d) Outside EDS

2022-11-02 09:46:18 Analysis of spectrum: Spectra from Area #1

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
6	C	K	67.78	8.12	32.22	3.71	3.25
8	O	K	17.65	4.08	11.53	2.46	0.57
41	Nb	K	4.57	2.50	55.25	8.16	0.57



2022-11-02 09:45:18 Analysis of spectrum: Spectra from Area #1

(h) Inside EDS

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6	C	K	0.00	0.24	0.00	0.03	0.00
8	O	K	8.27	2.42	1.53	0.36	1.29
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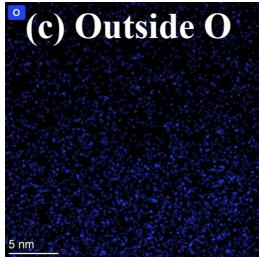
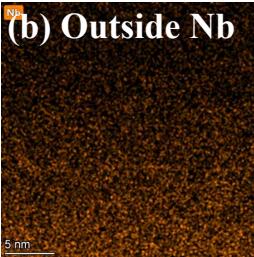
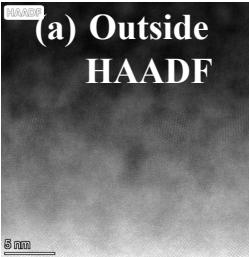
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2.4

Cross section



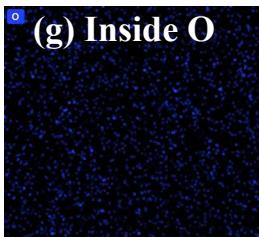
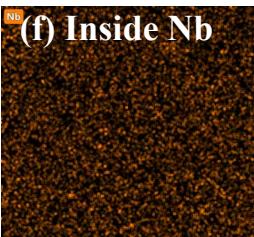
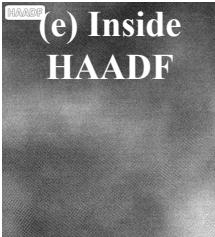
Baseline Nb sample



(d) Outside EDS

2022-11-02 09:46:18 Analysis of spectrum: Spectra from Area #1

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
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2022-11-02 09:45:18 Analysis of spectrum: Spectra from Area #1

(h) Inside EDS

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8	O	K	8.27	2.42	1.53	0.36	1.29
41	Nb	K	91.73	22.76	98.47	17.59	0.11

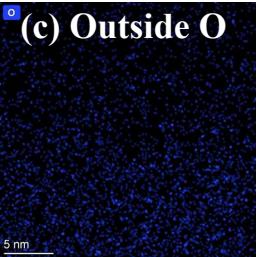
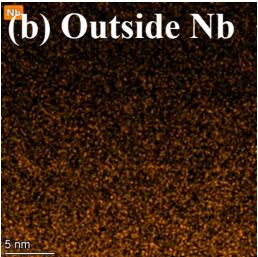
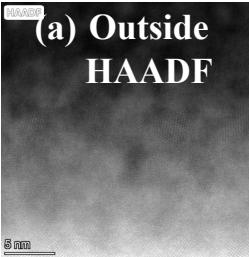
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2.4

Cross section



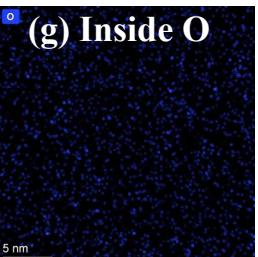
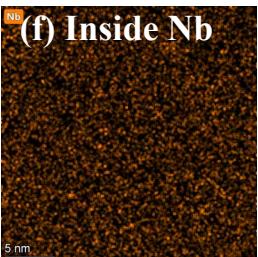
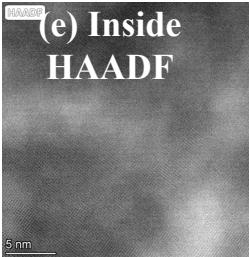
Baseline Nb sample



(d) Outside EDS

2022-11-02 09:46:18 Analysis of spectrum: Spectra from Area #1

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
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8	O	[K]	17.65	4.08	11.53	2.46	0.57
41	Nb	[K]	44.57	2.50	55.25	8.16	0.57



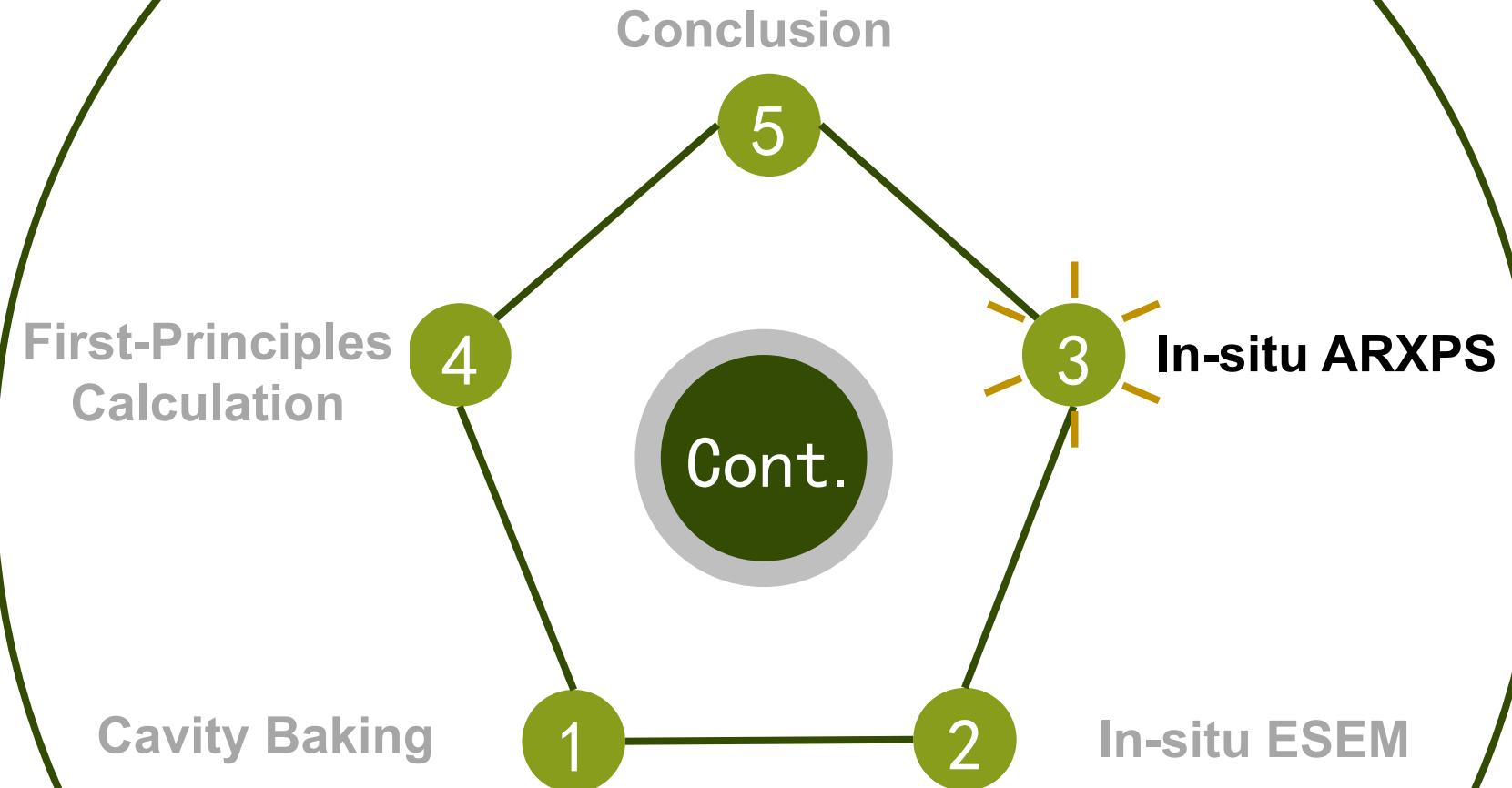
(h) Inside EDS

2022-11-02 09:45:18 Analysis of spectrum: Spectra from Area #1

Z	Element	Family	Atomic Fraction (%)	Atomic Error (%)	Mass Fraction (%)	Mass Error (%)	Fit error (%)
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8	O	[K]	8.27	2.43	1.53	0.36	1.29
41	Nb	[K]	91.73	22.76	98.47	17.59	0.11

- Out side O:Nb>1 , C:O>1
- Inside O:Nb<<1 , C:O ≈ 0
- Protection layer, Nb-O compounds, suppress the release of Hydrogen
- Inevitable adventitious carbon
- Interstitial O/C sources during baking

9



Introduction of in-situ ARXPS

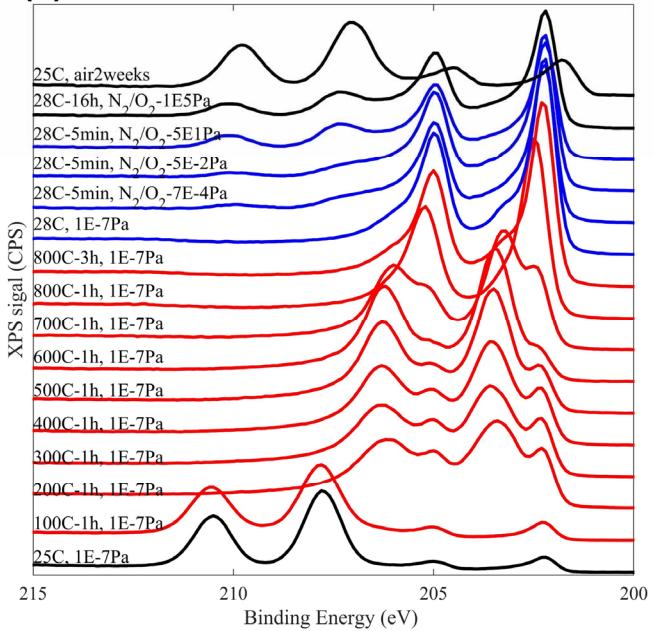


- Heavily chemically polished baseline samples
- In-situ angular resolved X-ray photoelectron spectroscopy (ARXPS):
the larger the detection angle, the shallower the detection depth
- Baking chamber is separated from measurement chamber for high
vacuum detection, quasi in-situ with accurate movement
- Raising from room temperature to 800°C with the gradient of 100°C,
baking and measuring
- Focus on the peaks of Nb (mainly Nb-O compounds) and C
(adventitious carbon and Nb-C compounds)

Temperature response of Nb-O



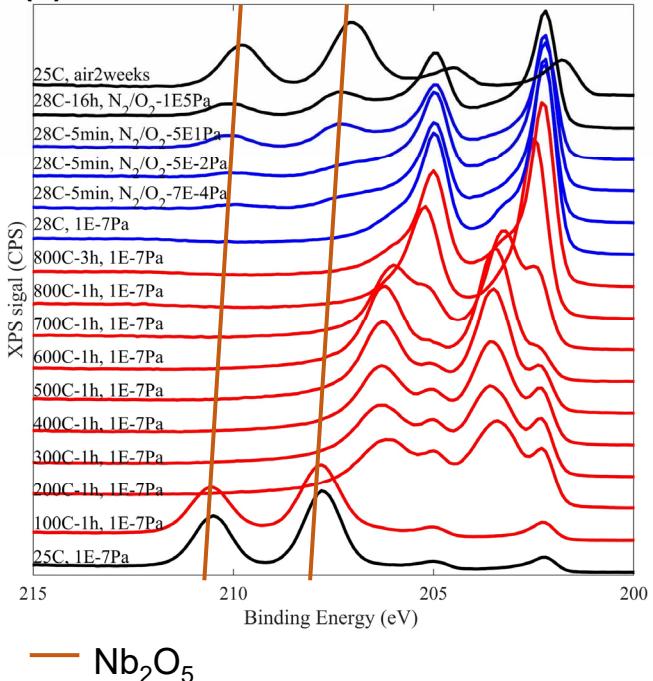
(a) 100-800°C



Temperature response of Nb-O



(a) 100-800°C

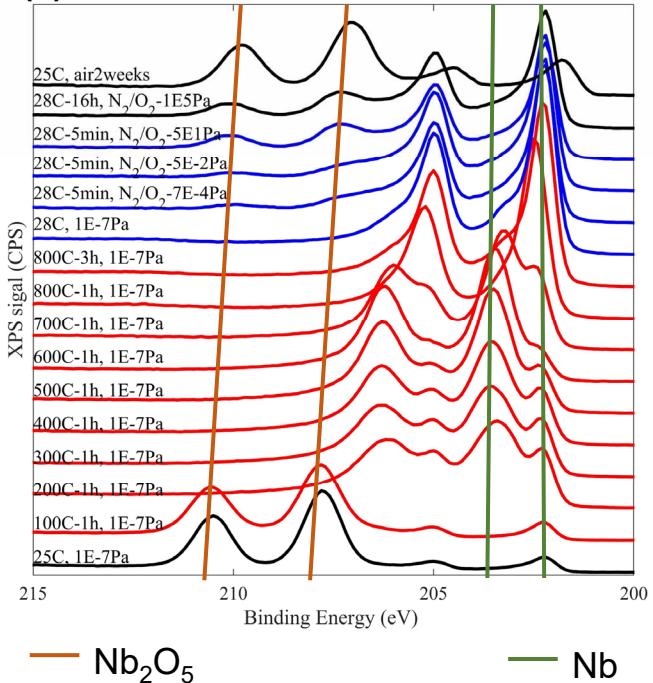


— Nb_2O_5

Temperature response of Nb-O



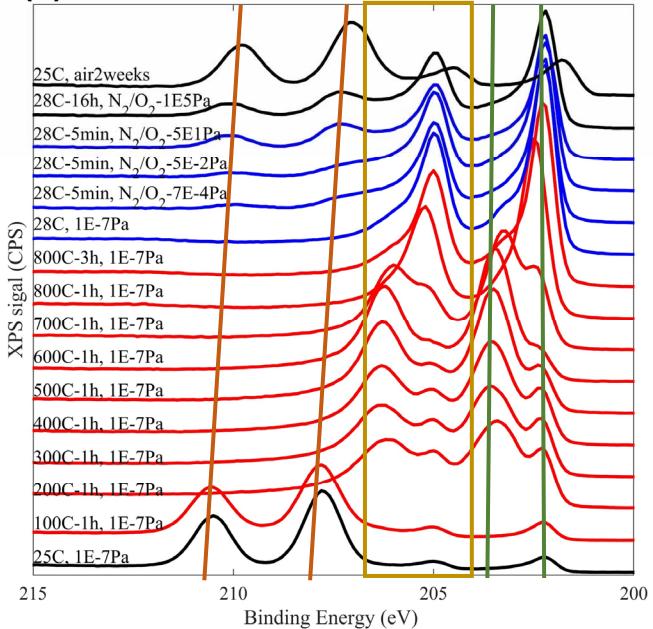
(a) 100-800°C



Temperature response of Nb-O



(a) 100-800°C



— Nb₂O₅ □ NbO₂/NbO/NbC — Nb

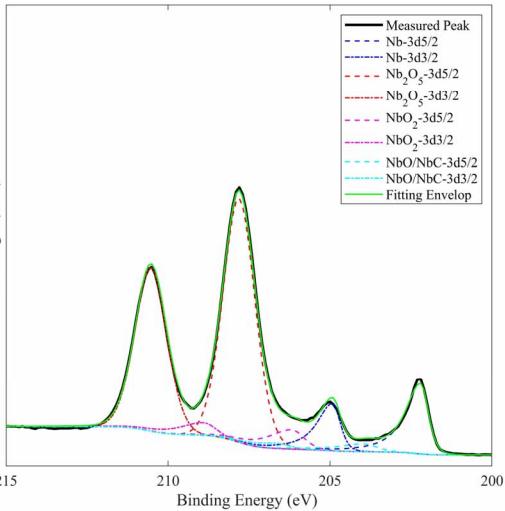
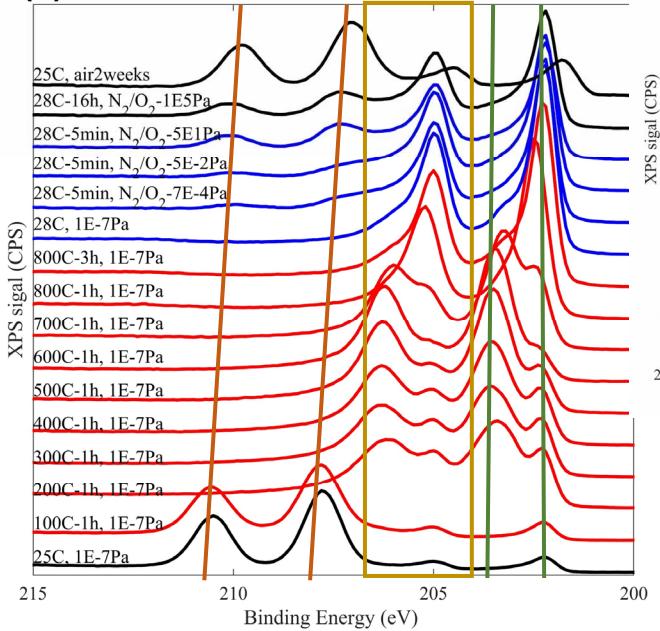
3.1

Temperature response of Nb-O

(b) 25°C

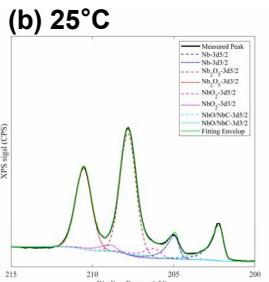
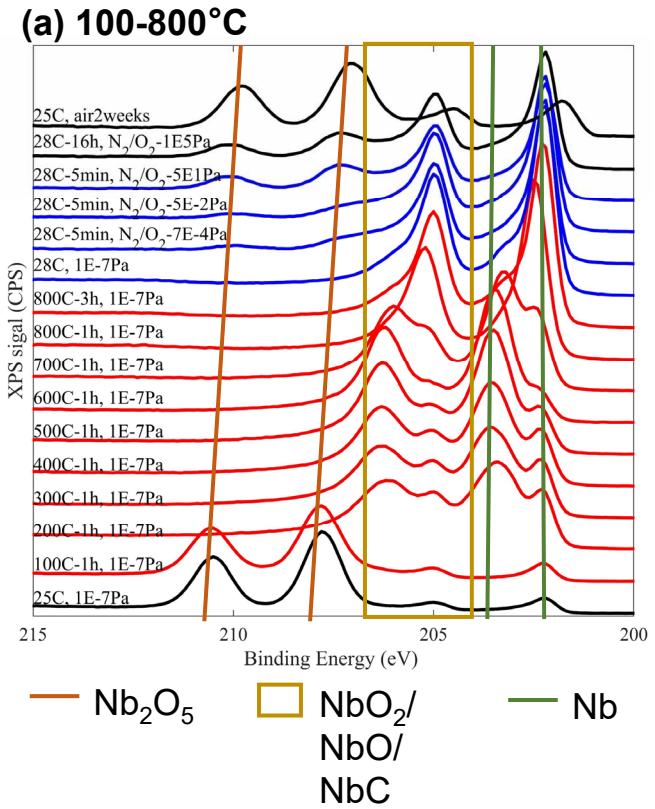


(a) 100-800°C



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Temperature response of Nb-O

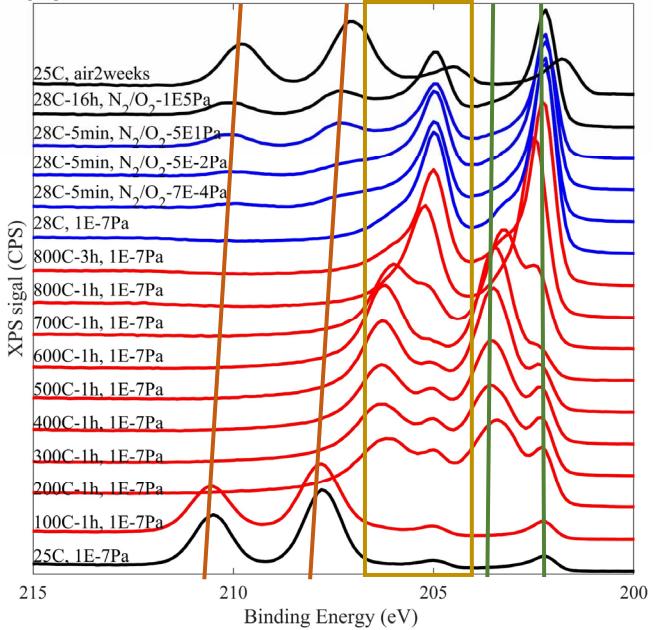


Temperature response of Nb-O

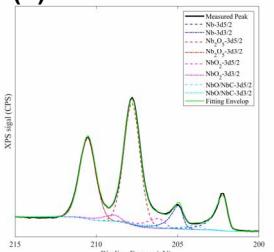
(c) 400°C 1 h



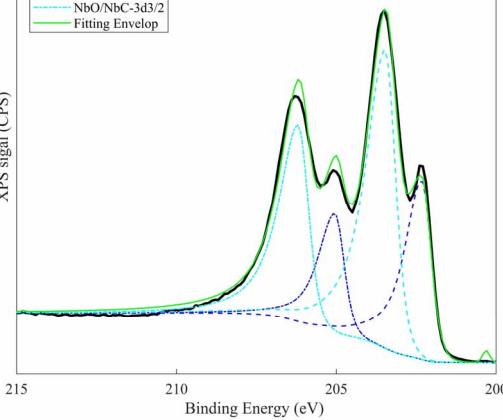
(a) 100-800°C



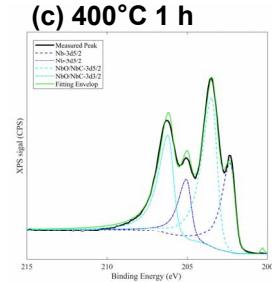
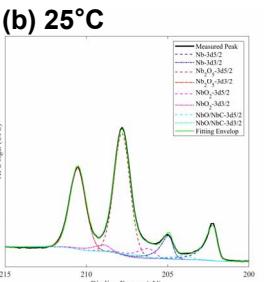
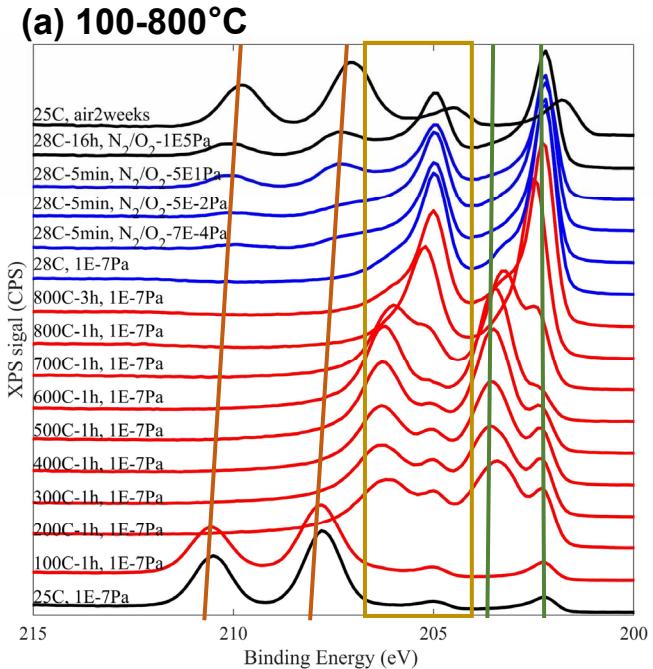
(b) 25°C



XPS signal (CPS)



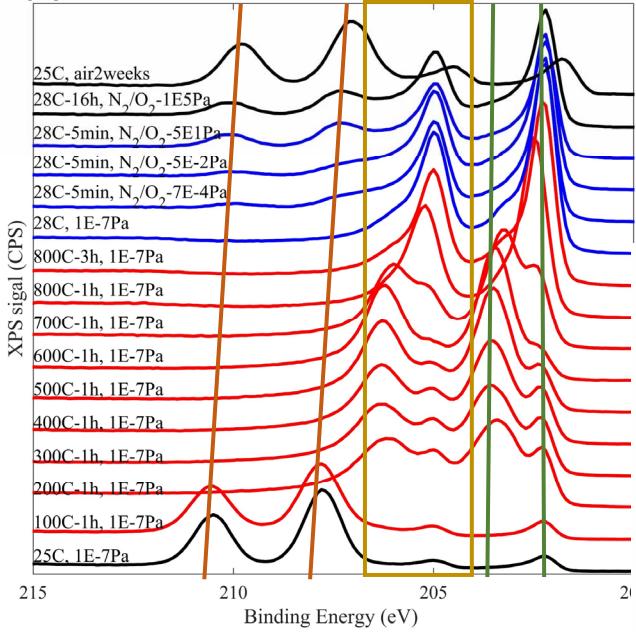
Temperature response of Nb-O



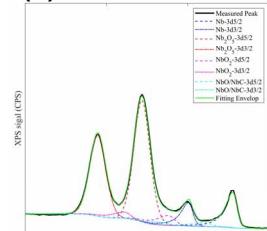
Temperature response of Nb-O



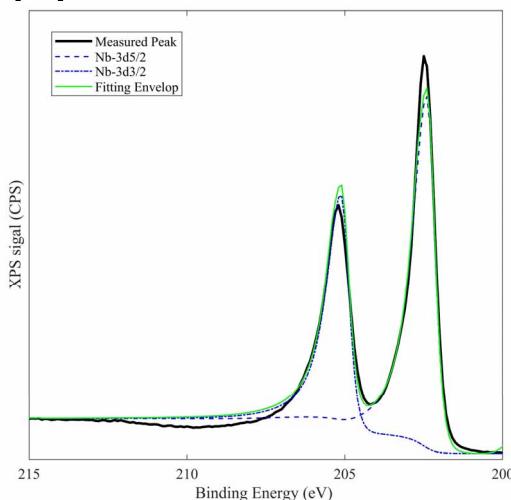
(a) 100-800°C



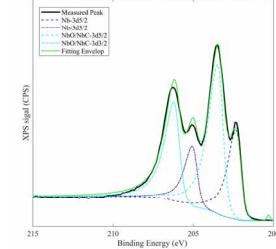
(b) 25°C



(d) 800°C 3 h



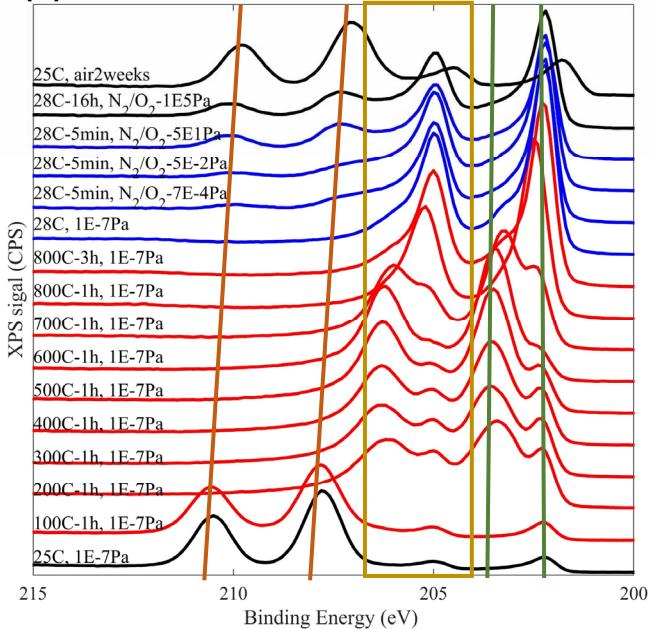
(c) 400°C 1 h



Temperature response of Nb-O

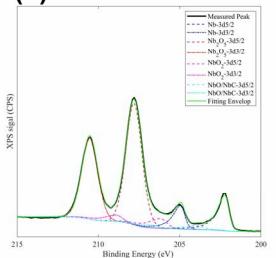


(a) 100-800°C

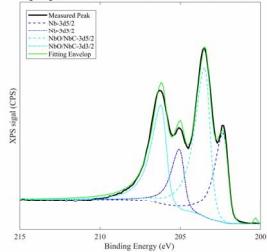
 Nb_2O_5 $\text{NbO}_2/\text{NbO}/\text{NbC}$

Nb

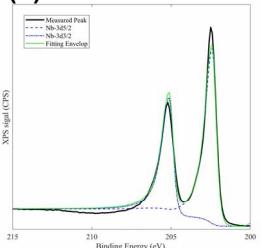
(b) 25°C



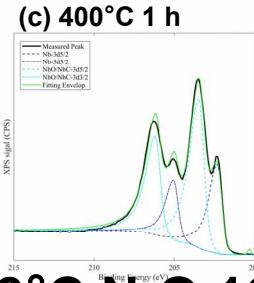
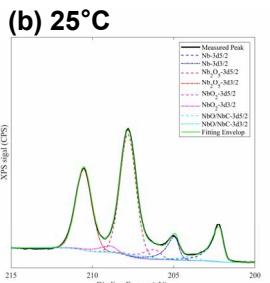
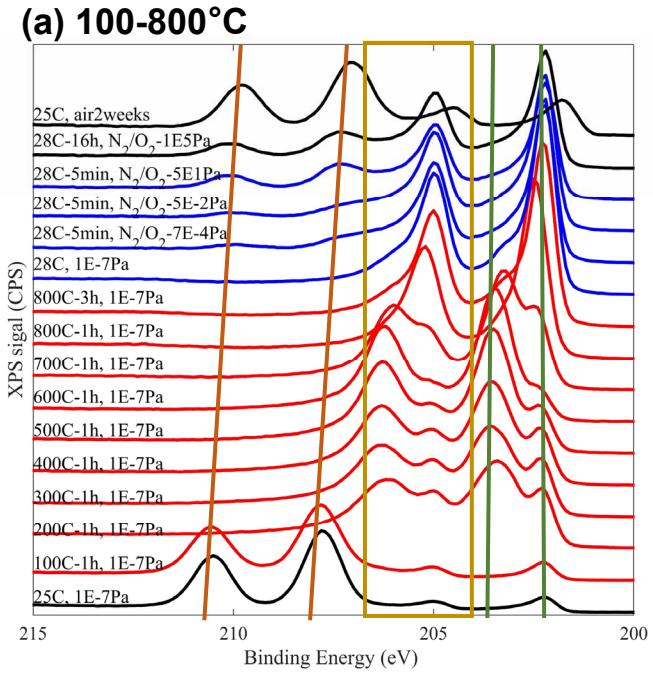
(c) 400°C 1 h



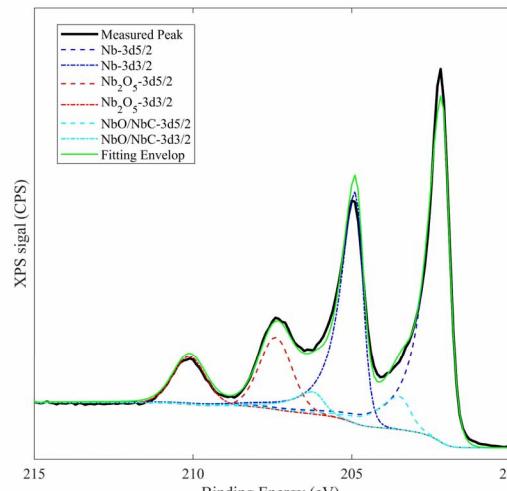
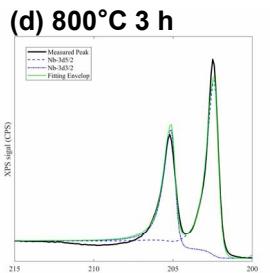
(d) 800°C 3 h



Temperature response of Nb-O



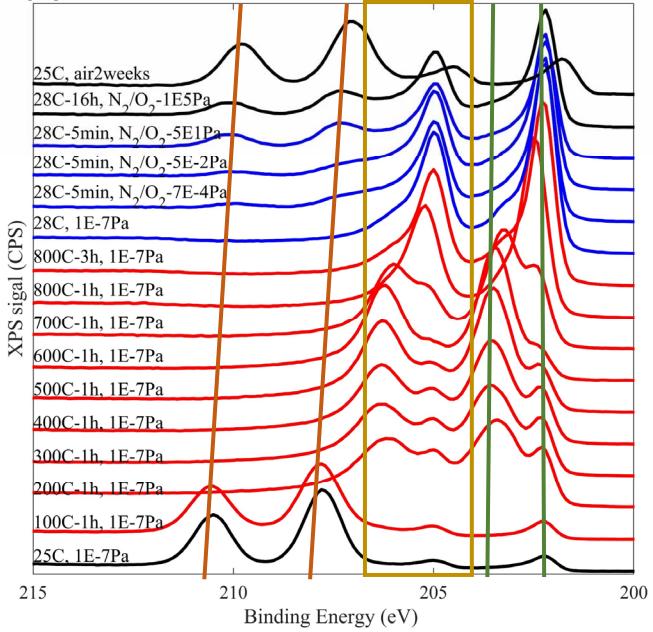
(e) 28°C N-O 16 h



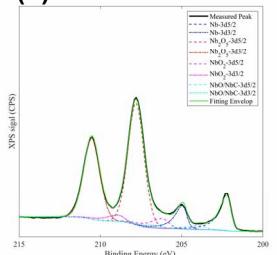
Temperature response of Nb-O



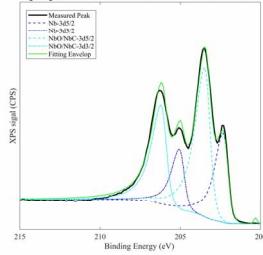
(a) 100-800°C



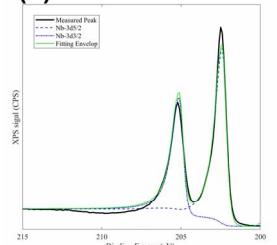
(b) 25°C



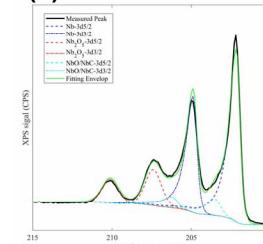
(c) 400°C 1 h



(d) 800°C 3 h



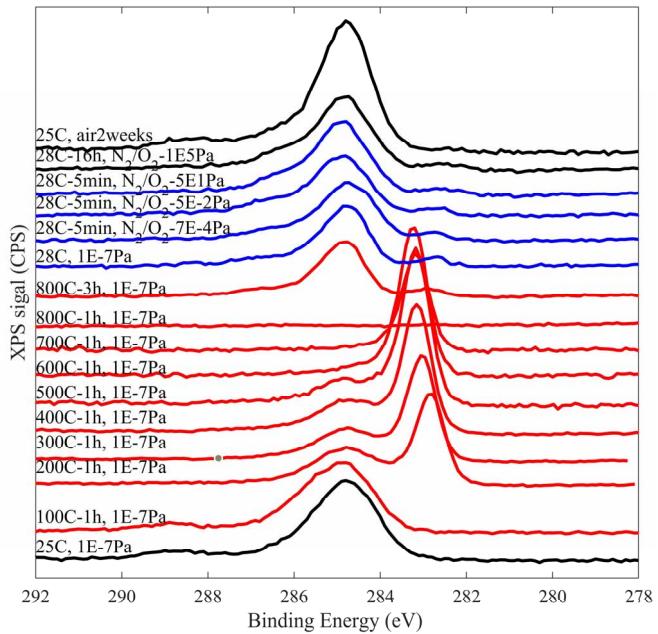
(e) 28°C N-O 16 h



Temperature response of C



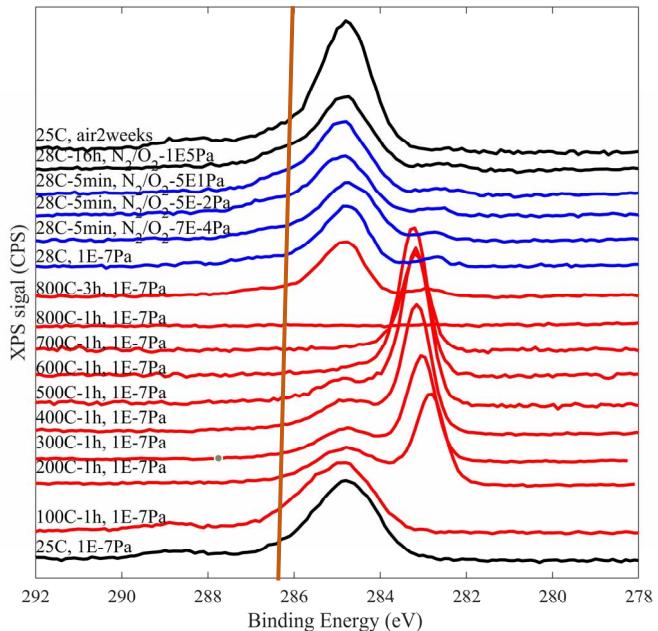
(a) 100-800°C



Temperature response of C



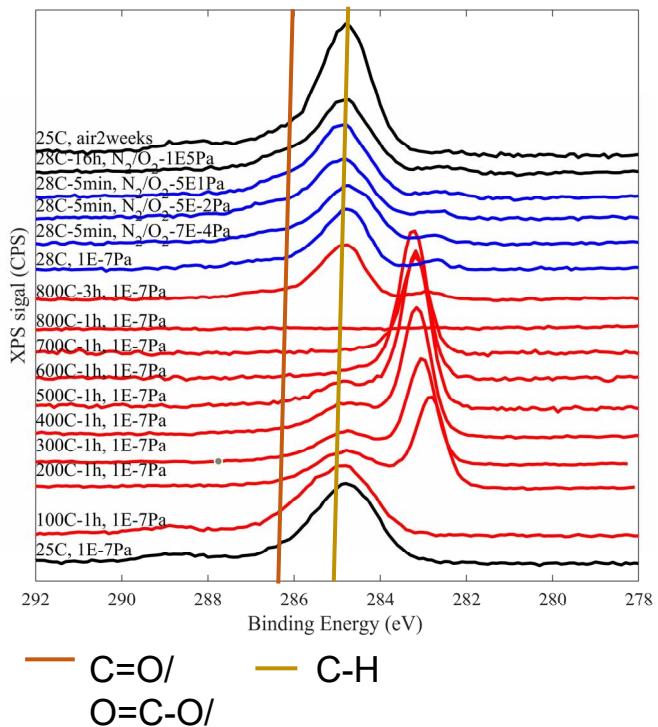
(a) 100-800°C



Temperature response of C



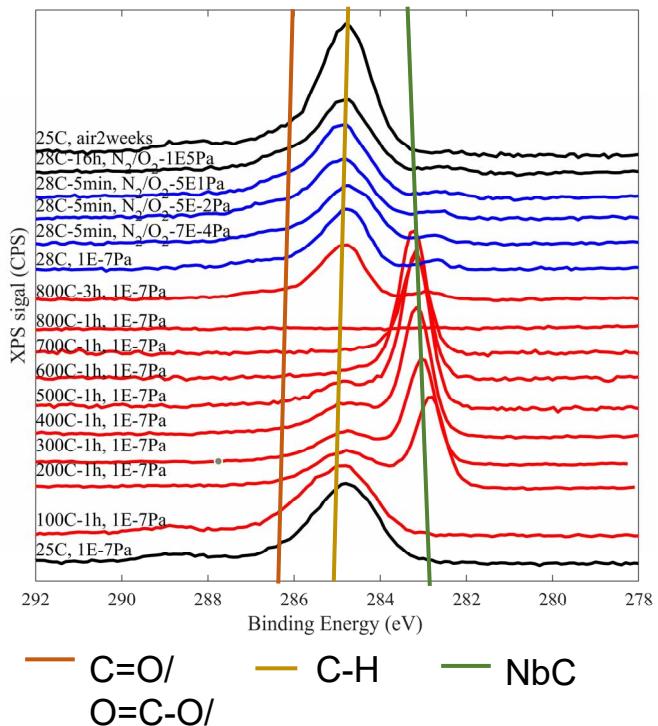
(a) 100-800°C



Temperature response of C



(a) 100-800°C

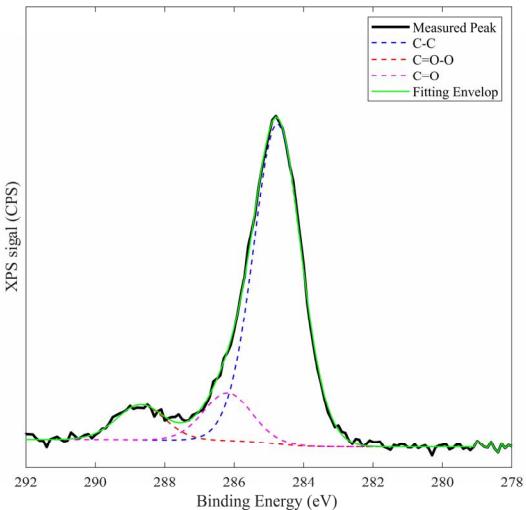
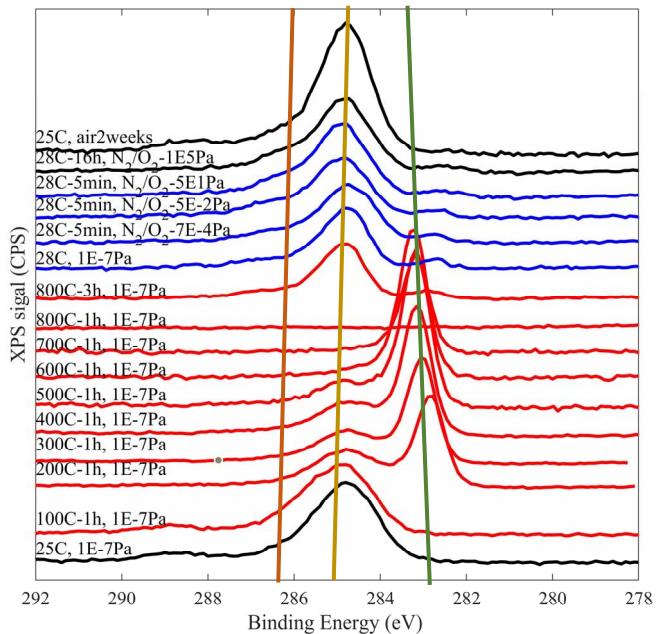


Temperature response of C

(b) 25°C



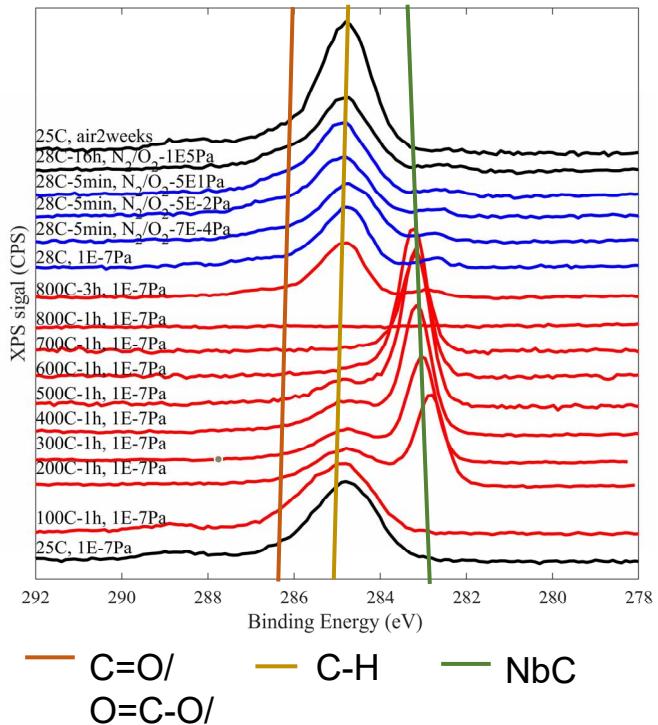
(a) 100-800°C



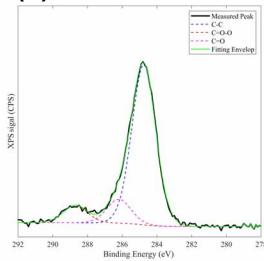
Temperature response of C



(a) 100-800°C



(b) 25°C



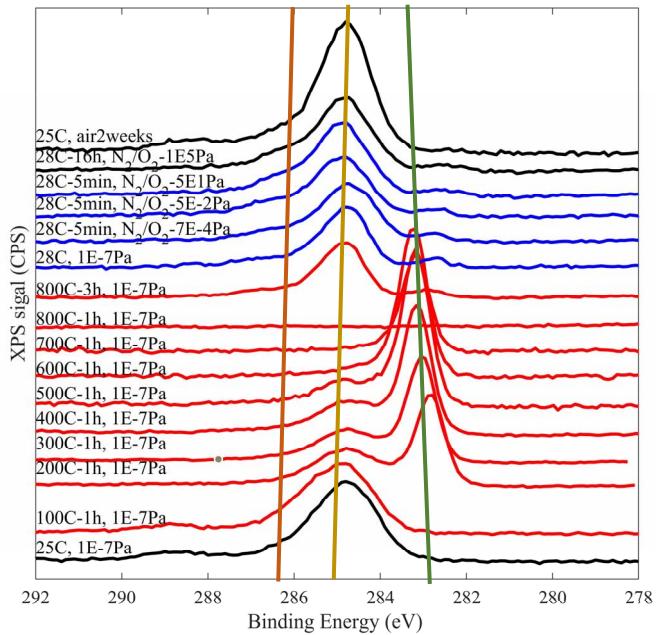
3.2

Temperature response of C

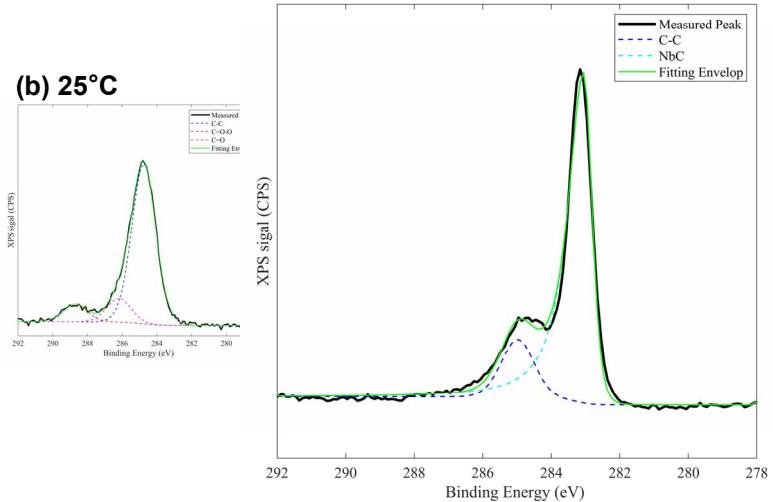
(c) 400°C 1 h



(a) 100-800°C



(b) 25°C

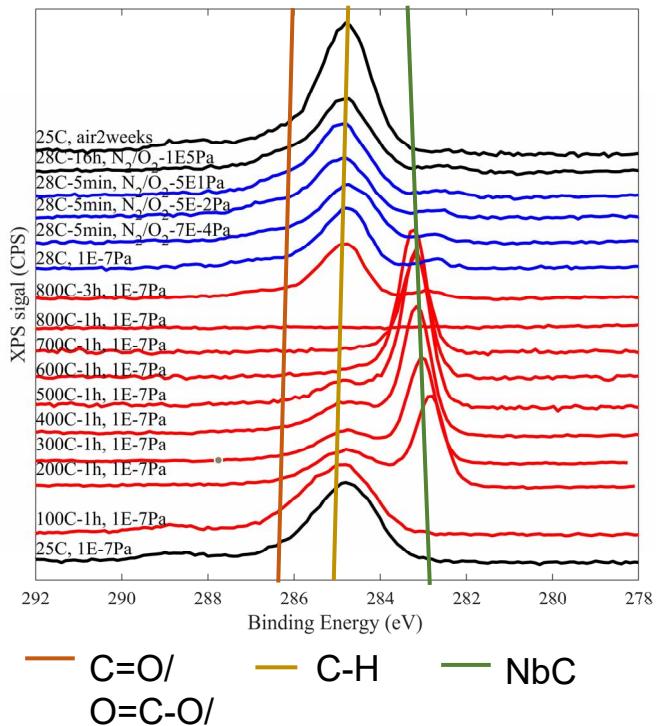


13

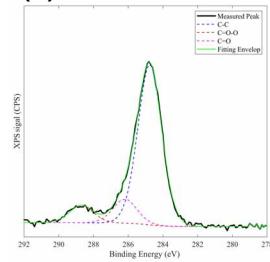
Temperature response of C



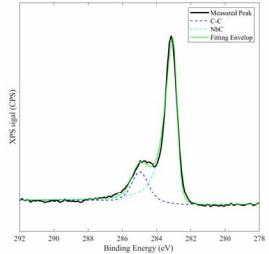
(a) 100-800°C



(b) 25°C



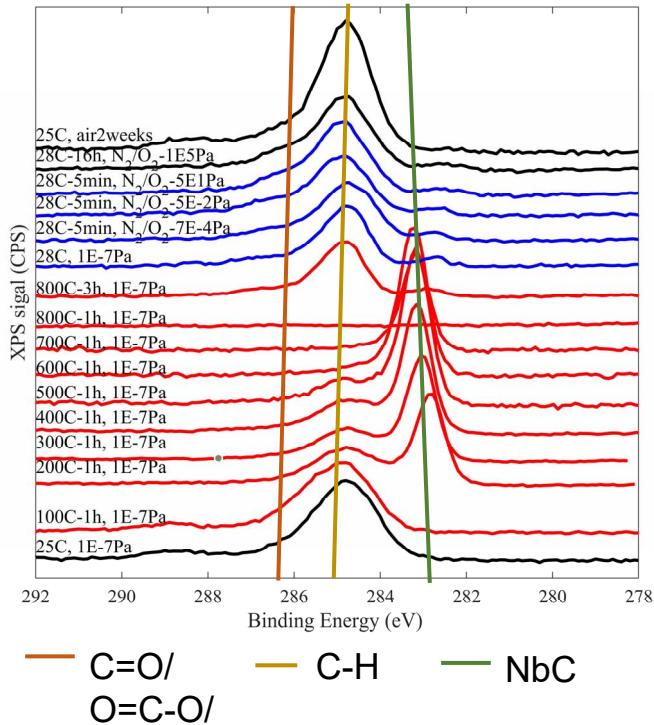
(c) 400°C 1 h



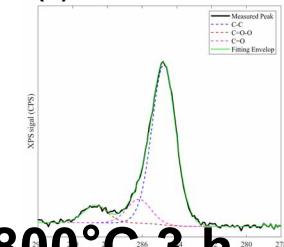
Temperature response of C



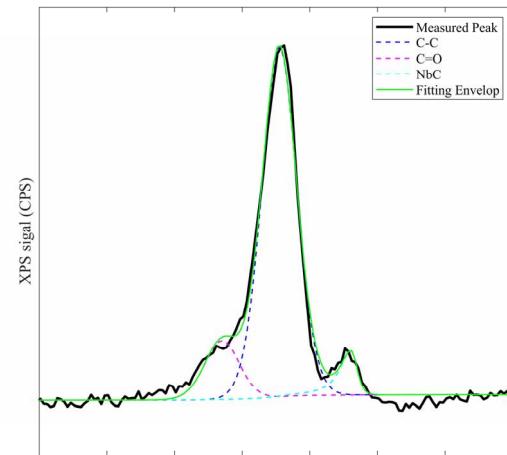
(a) 100-800°C



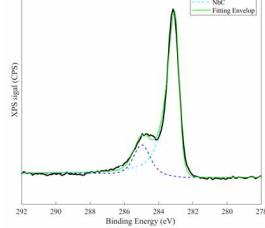
(b) 25°C



(d) 800°C 3 h



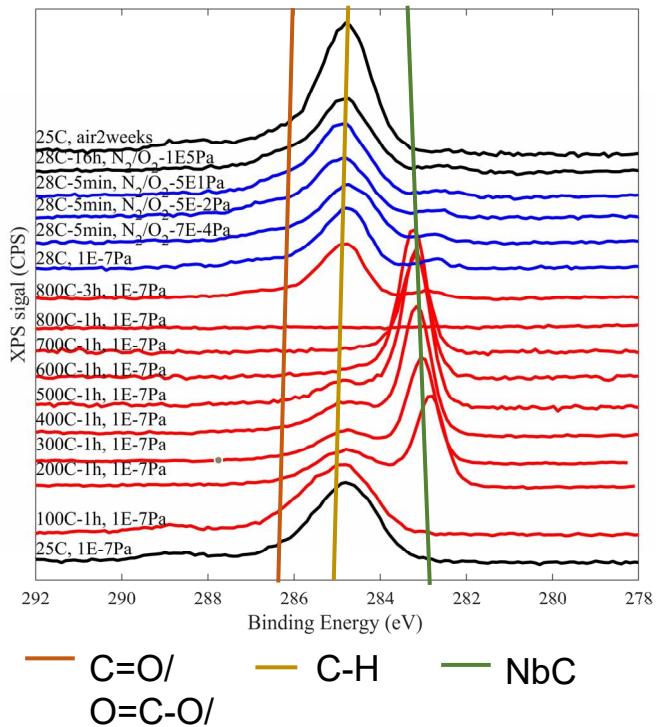
(c) 400°C 1 h



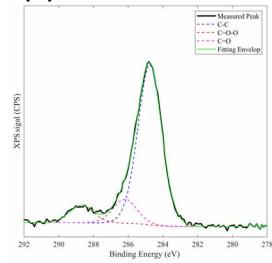
Temperature response of C



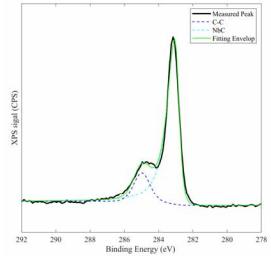
(a) 100-800°C



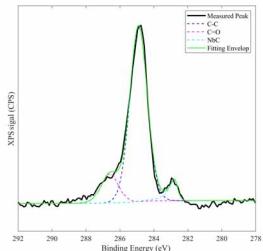
(b) 25°C



(c) 400°C 1 h



(d) 800°C 3 h

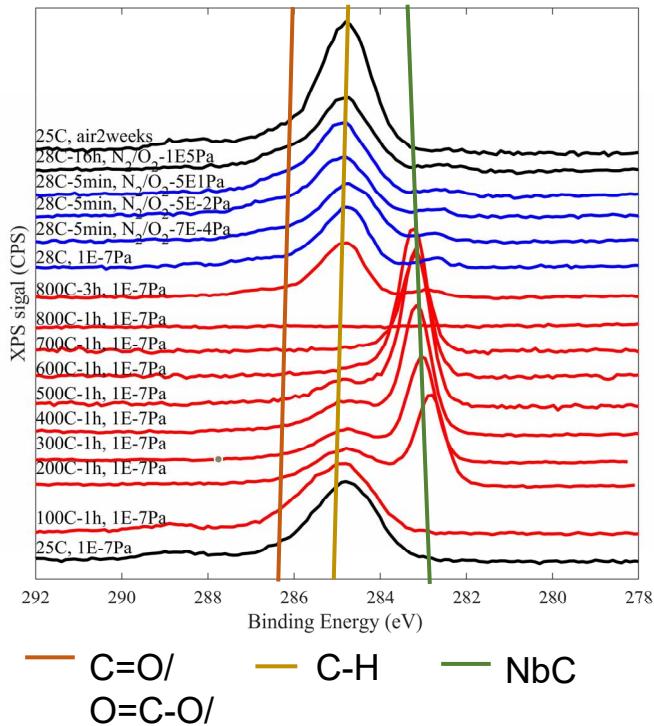


3.2

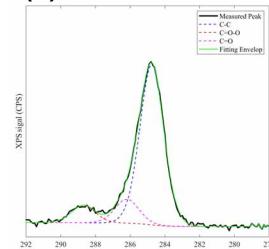
Temperature response of C



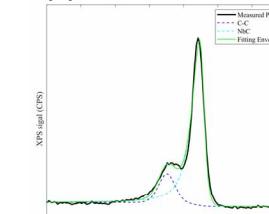
(a) 100-800°C



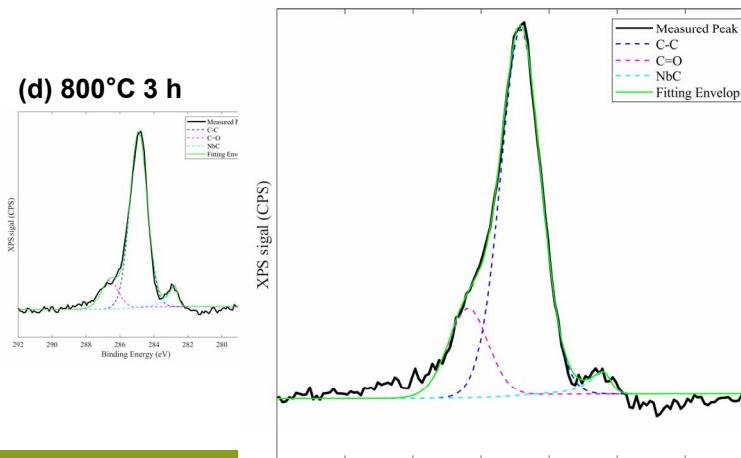
(b) 25°C



(c) 400°C 1 h



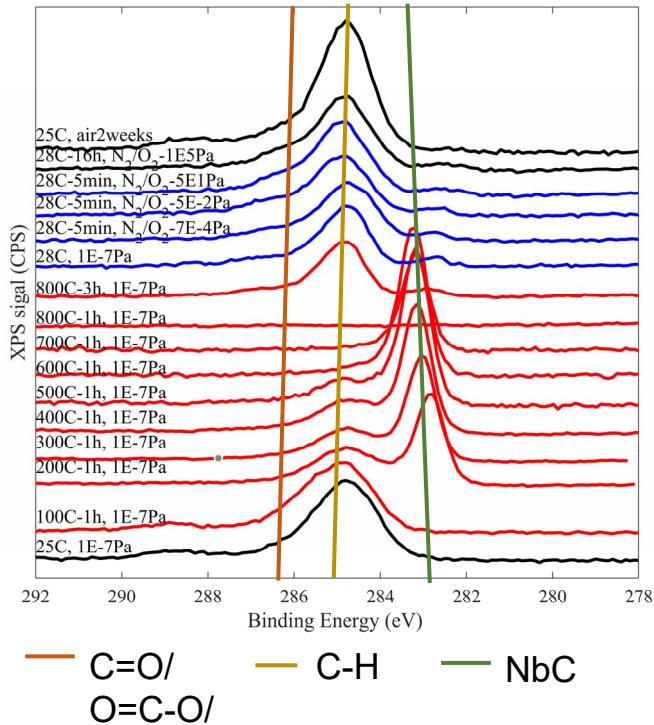
(e) 28°C N-O 16 h



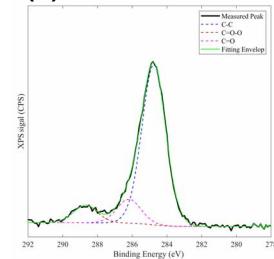
Temperature response of C



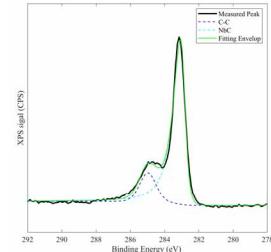
(a) 100-800°C



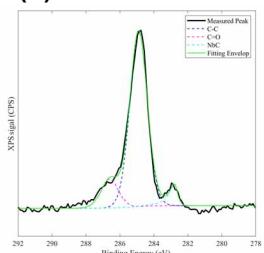
(b) 25°C



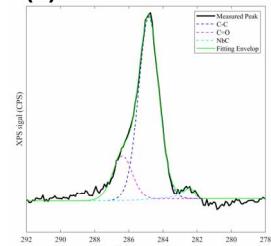
(c) 400°C 1 h



(d) 800°C 3 h



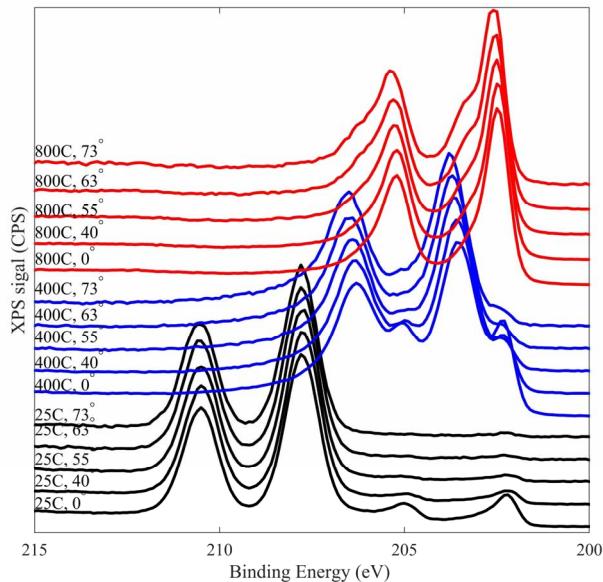
(e) 28°C N-O 16 h



Depth resolution by changing angle



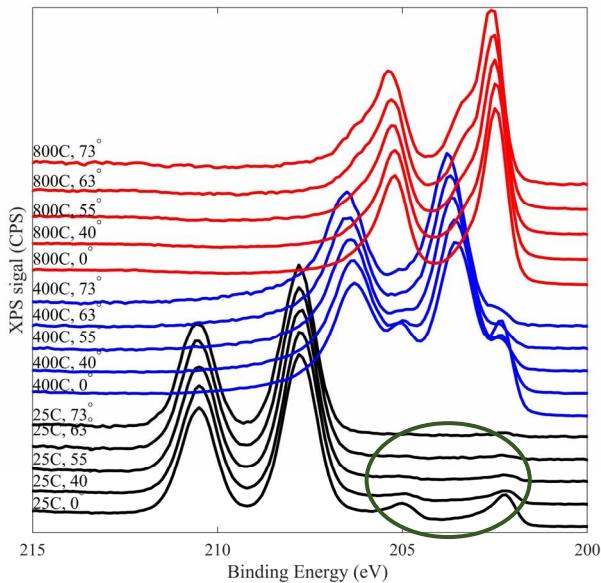
(a) 25, 400, 800°C - Nb Peaks



Depth resolution by changing angle



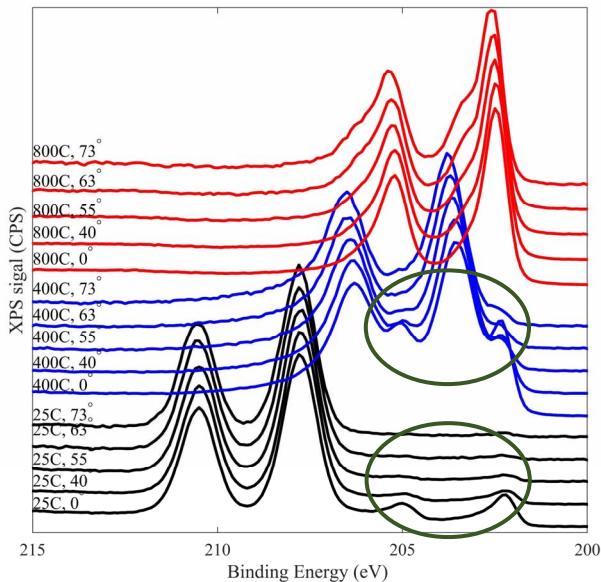
(a) 25, 400, 800°C - Nb Peaks



Depth resolution by changing angle



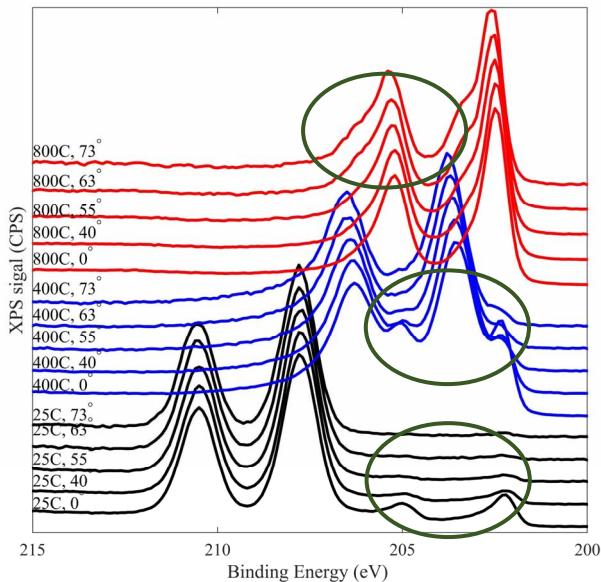
(a) 25, 400, 800°C - Nb Peaks



Depth resolution by changing angle



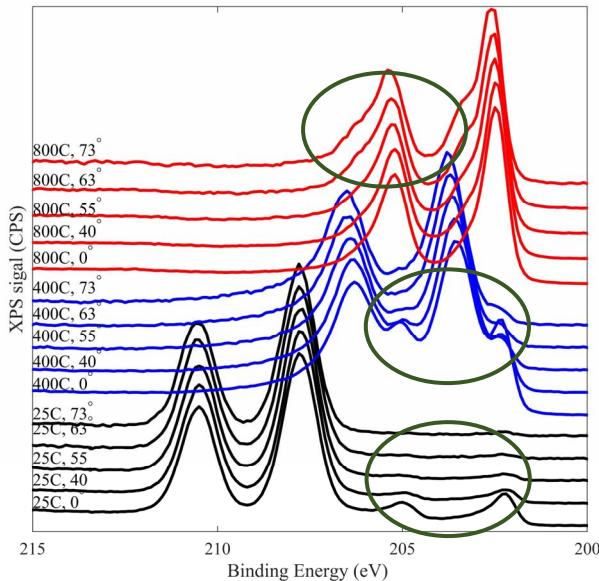
(a) 25, 400, 800°C - Nb Peaks



Depth resolution by changing angle



(a) 25, 400, 800°C - Nb Peaks

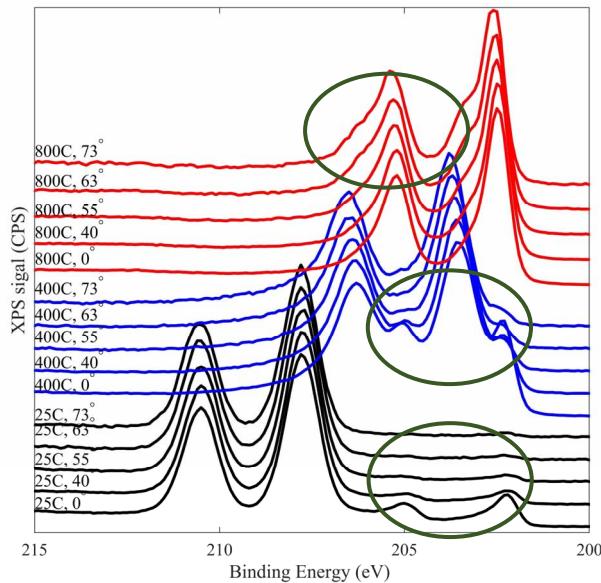


- Surface-Higher valence Nb
- Inner-Lower valence Nb

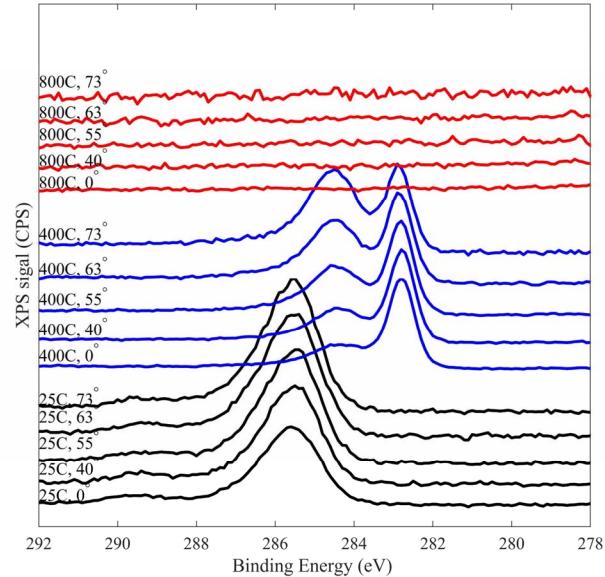
Depth resolution by changing angle



(a) 25, 400, 800°C - Nb Peaks



(b) 25, 400, 800°C - C Peaks

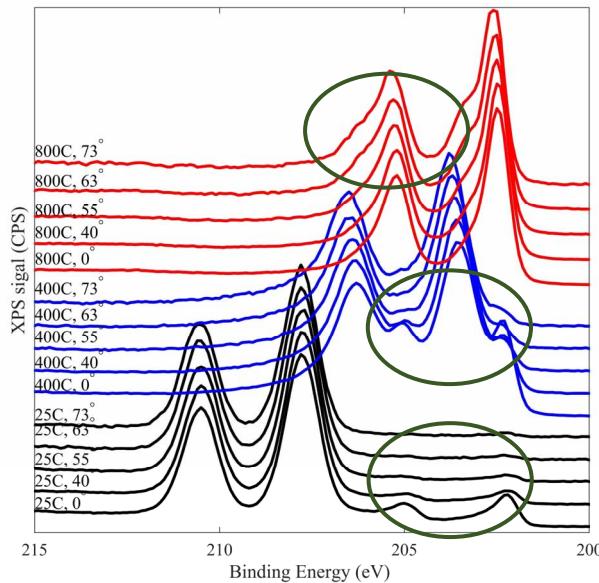


- Surface-Higher valence Nb
- Inner-Lower valence Nb

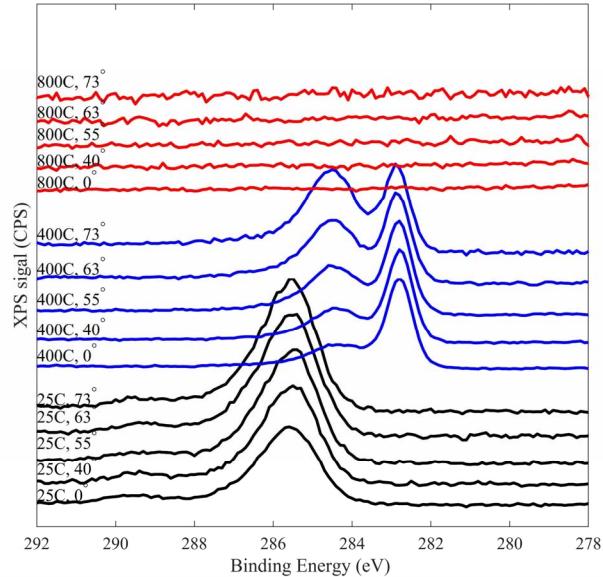
Depth resolution by changing angle



(a) 25, 400, 800°C - Nb Peaks



(b) 25, 400, 800°C - C Peaks



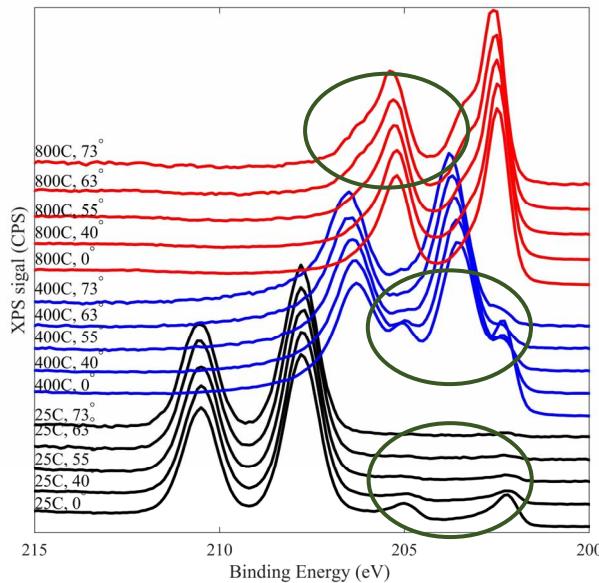
- Surface-Higher valence Nb
- Inner-Lower valence Nb

- Surface-Adventitious C
- Inner-Nb-C Compound

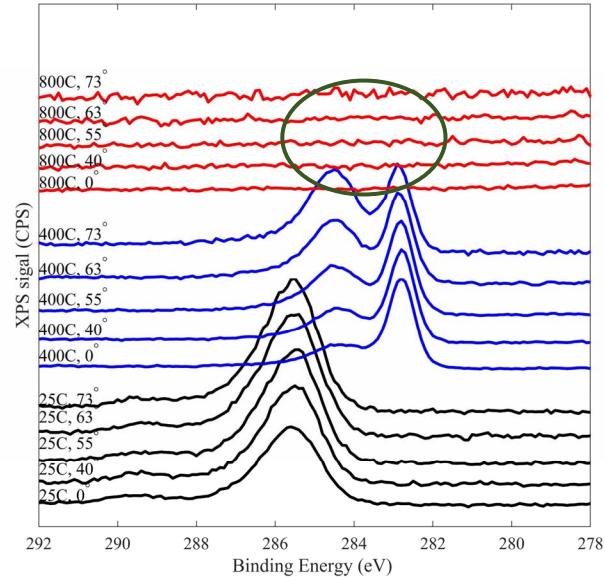
Depth resolution by changing angle



(a) 25, 400, 800°C - Nb Peaks



(b) 25, 400, 800°C - C Peaks



- Surface-Higher valence Nb
- Inner-Lower valence Nb

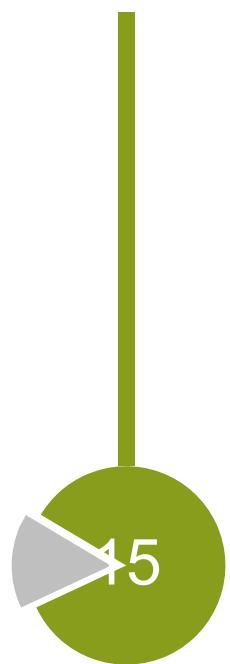
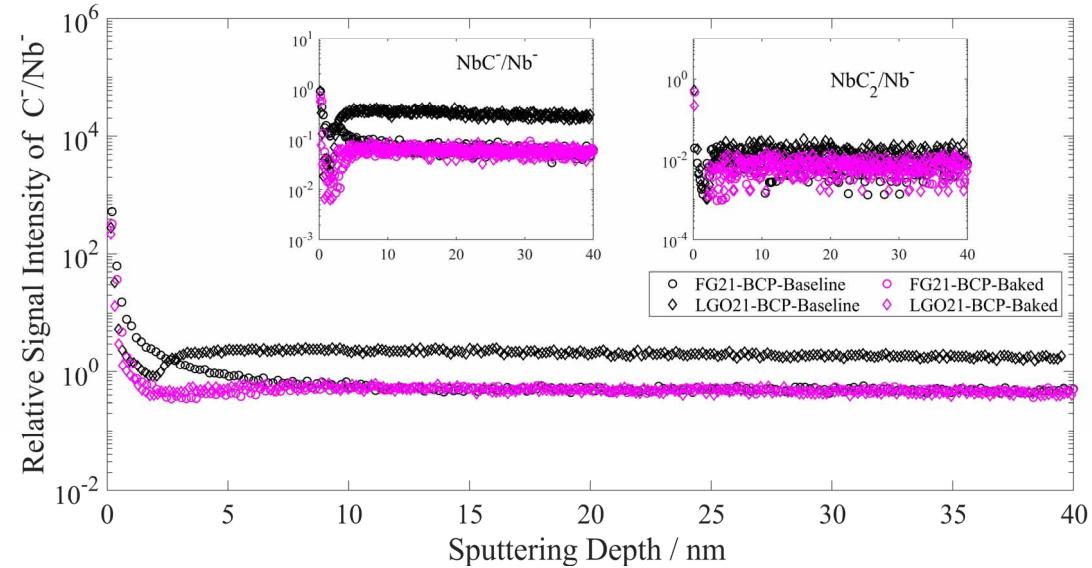
- Surface-Adventitious C
- Inner-Nb-C Compound



TOF-SIMS results



Before and after baking

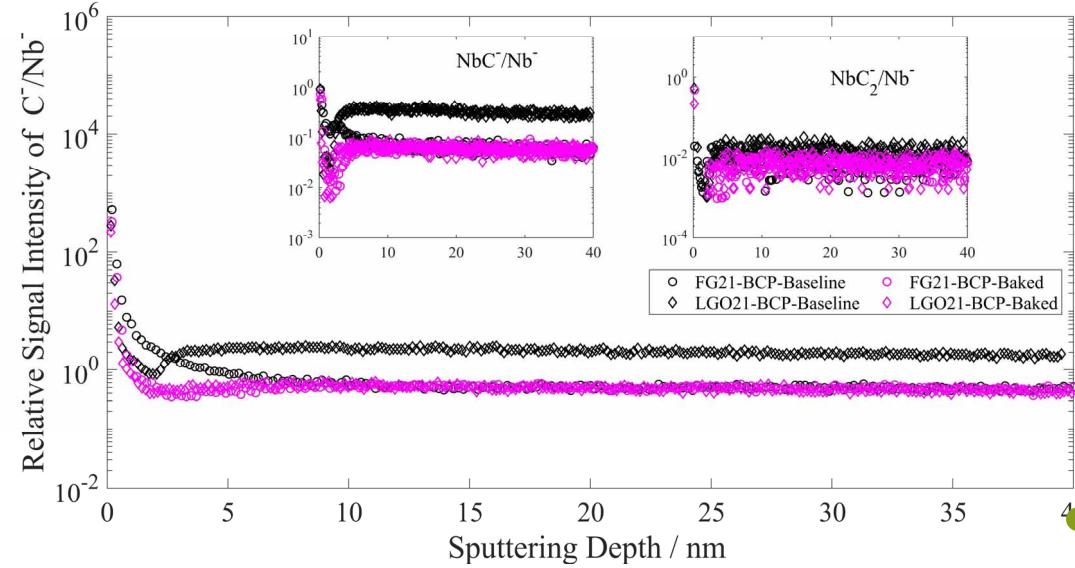




TOF-SIMS results

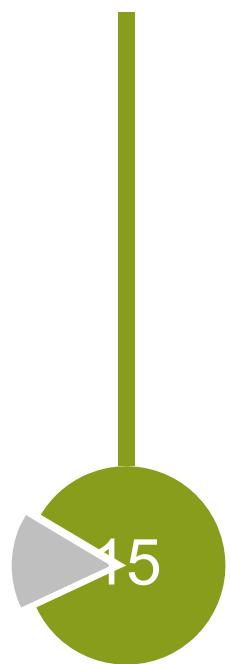


Before and after baking



40

C: C, NbC, NbC₂

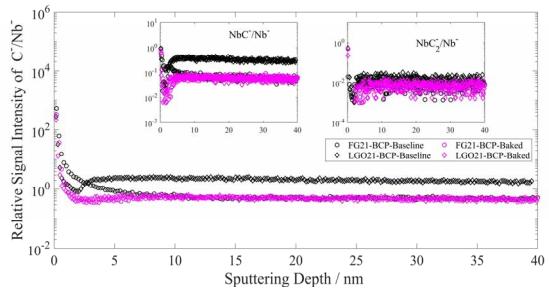


3.4

TOF-SIMS results



Before and after baking



- C: C, NbC, NbC_2

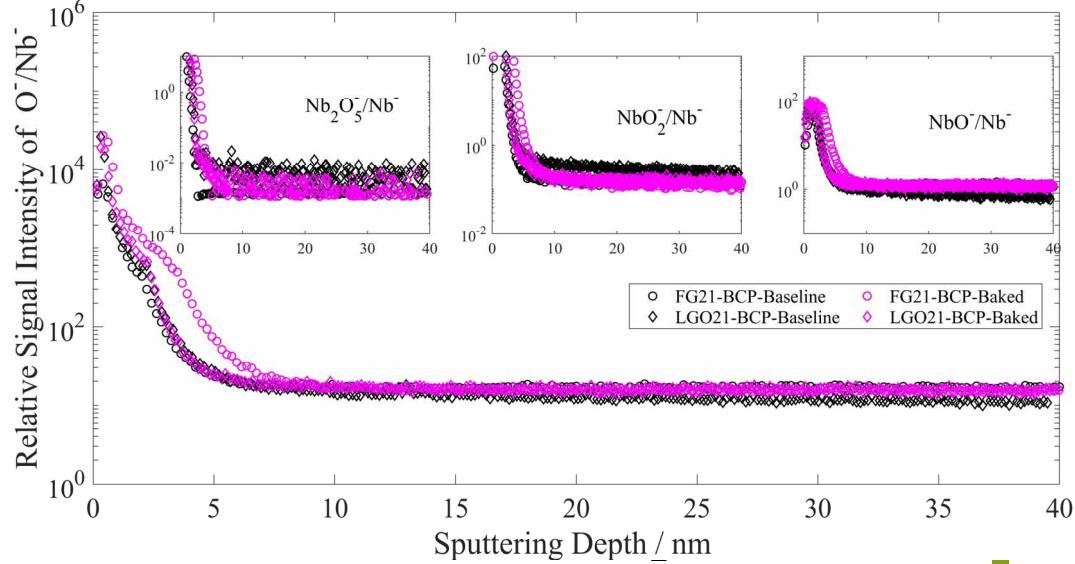
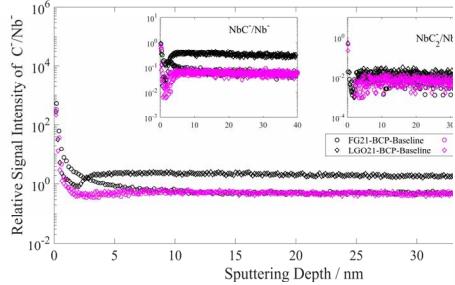
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3.4

TOF-SIMS results



Before and after baking



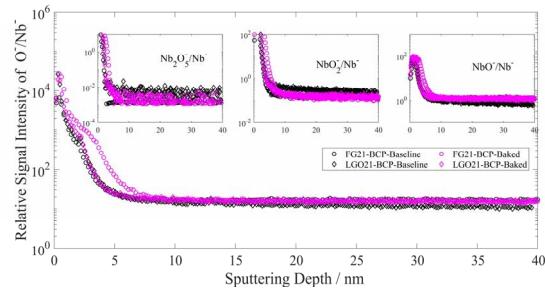
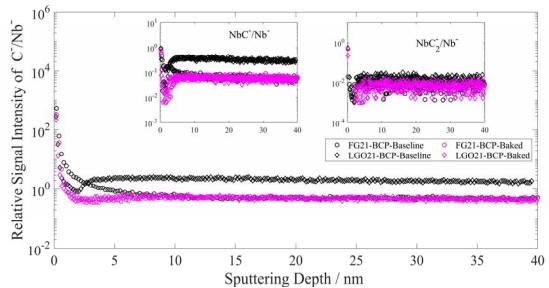
45

3.4

TOF-SIMS results



Before and after baking



- C: C, NbC, NbC₂
- O: O, Nb₂O₅, NbO₂, NbO

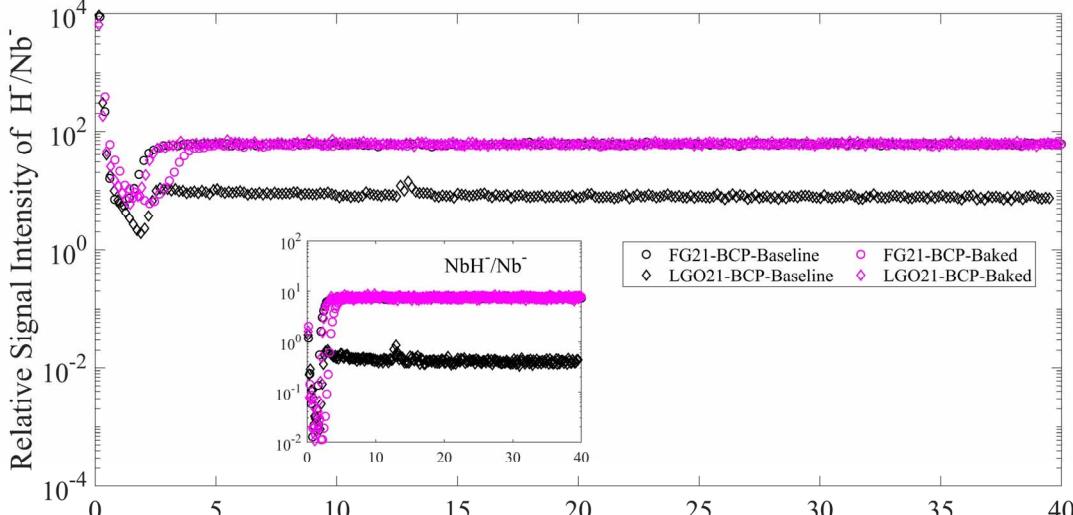
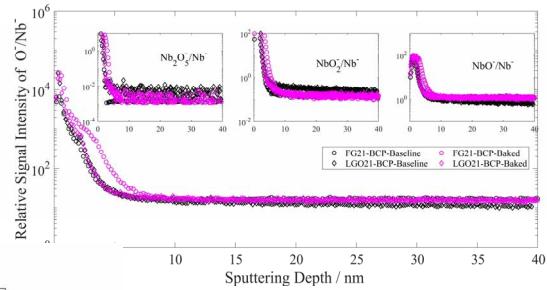
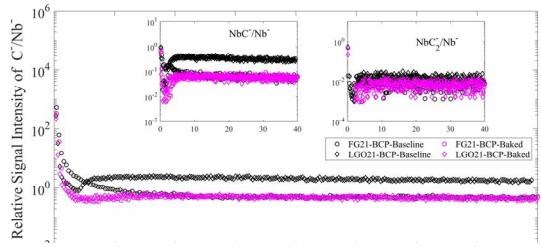
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3.4

TOF-SIMS results



Before and after baking



, NbC , NbC_2

, Nb_2O_5 , NbO_2 , NbO

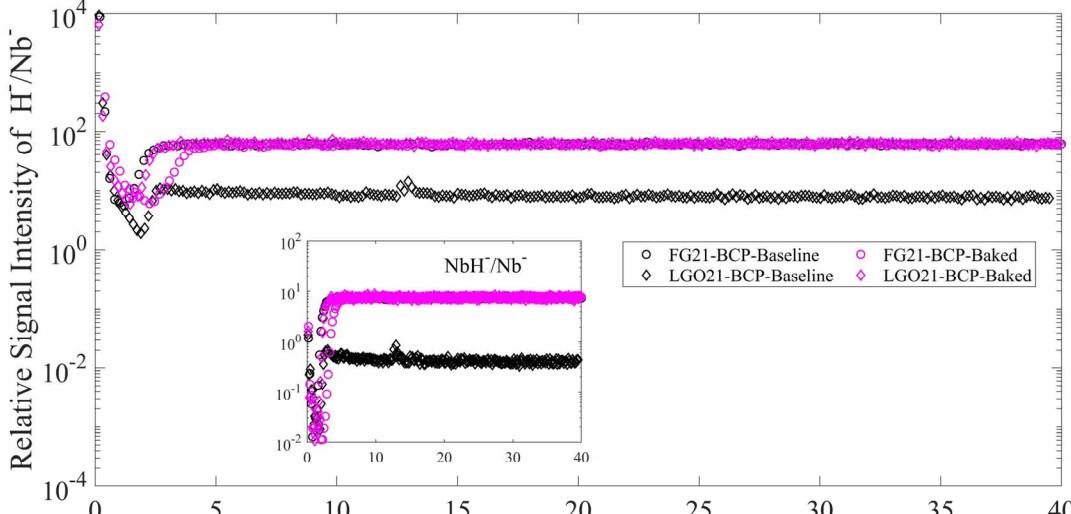
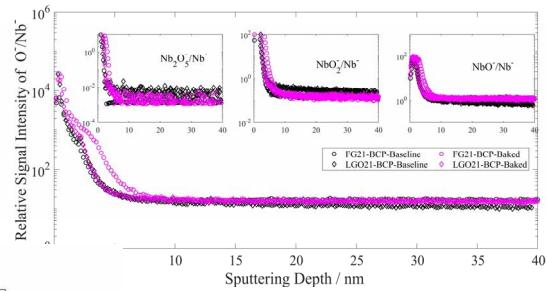
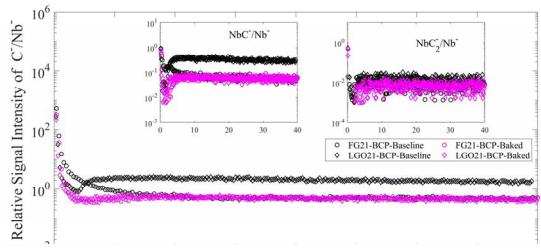
45

3.4

TOF-SIMS results



Before and after baking



; NbC , NbC_2

; Nb_2O_5 , NbO_2 , NbO

{, NbH

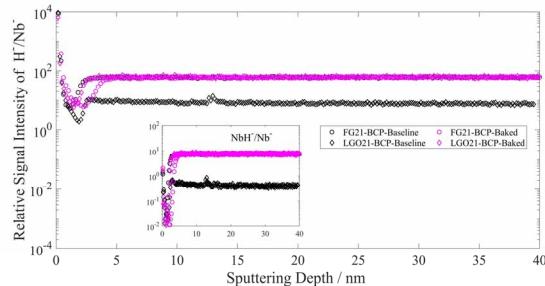
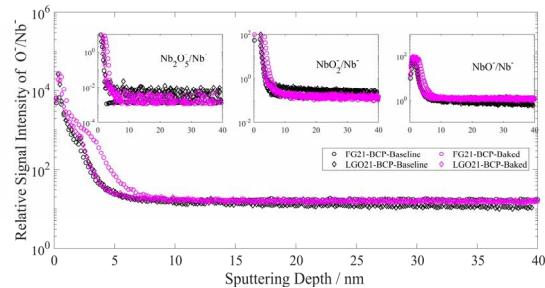
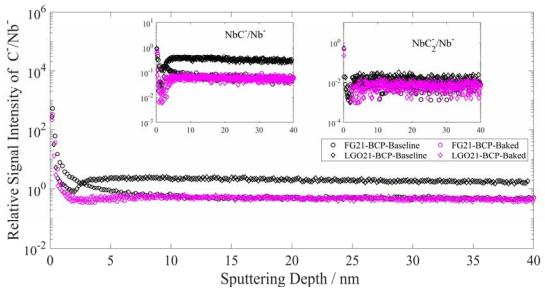
45

3.4

TOF-SIMS results



Before and after baking



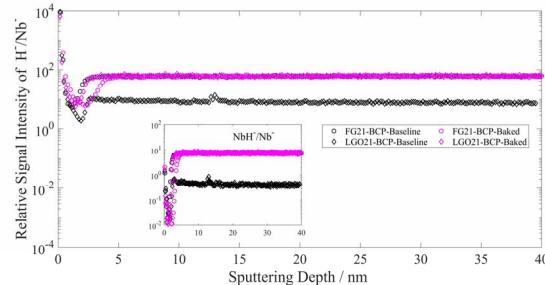
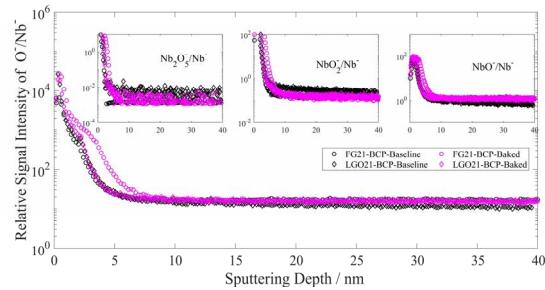
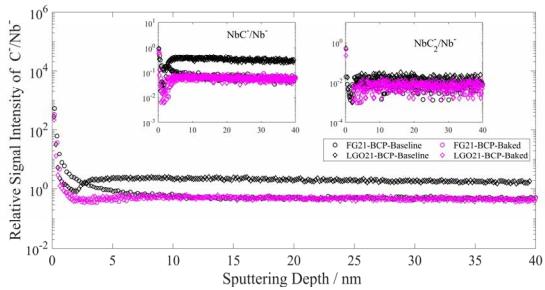
- C: C, NbC, NbC₂
- O: O, Nb₂O₅, NbO₂, NbO
- H: H, NbH

45

TOF-SIMS results



Before and after baking



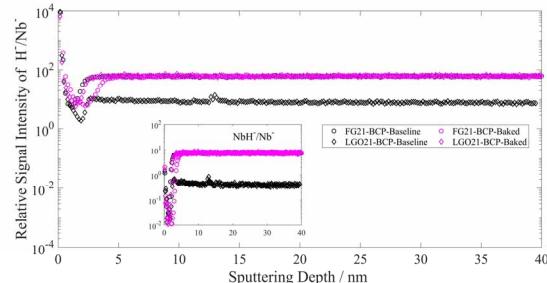
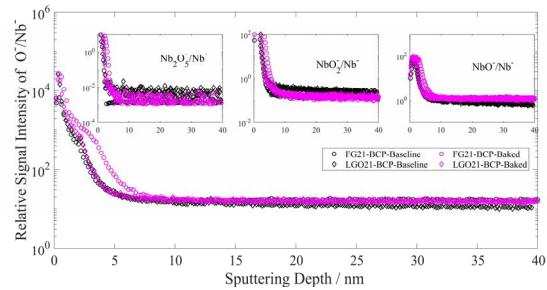
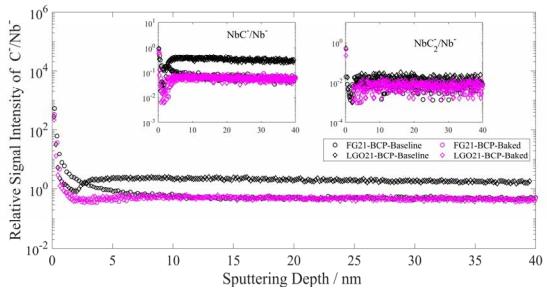
- C: C, NbC, NbC_2
- O: O, Nb_2O_5 , NbO_2 , NbO
- H: H, NbH
- Fine grain: C →, O →, H →

3.4

TOF-SIMS results

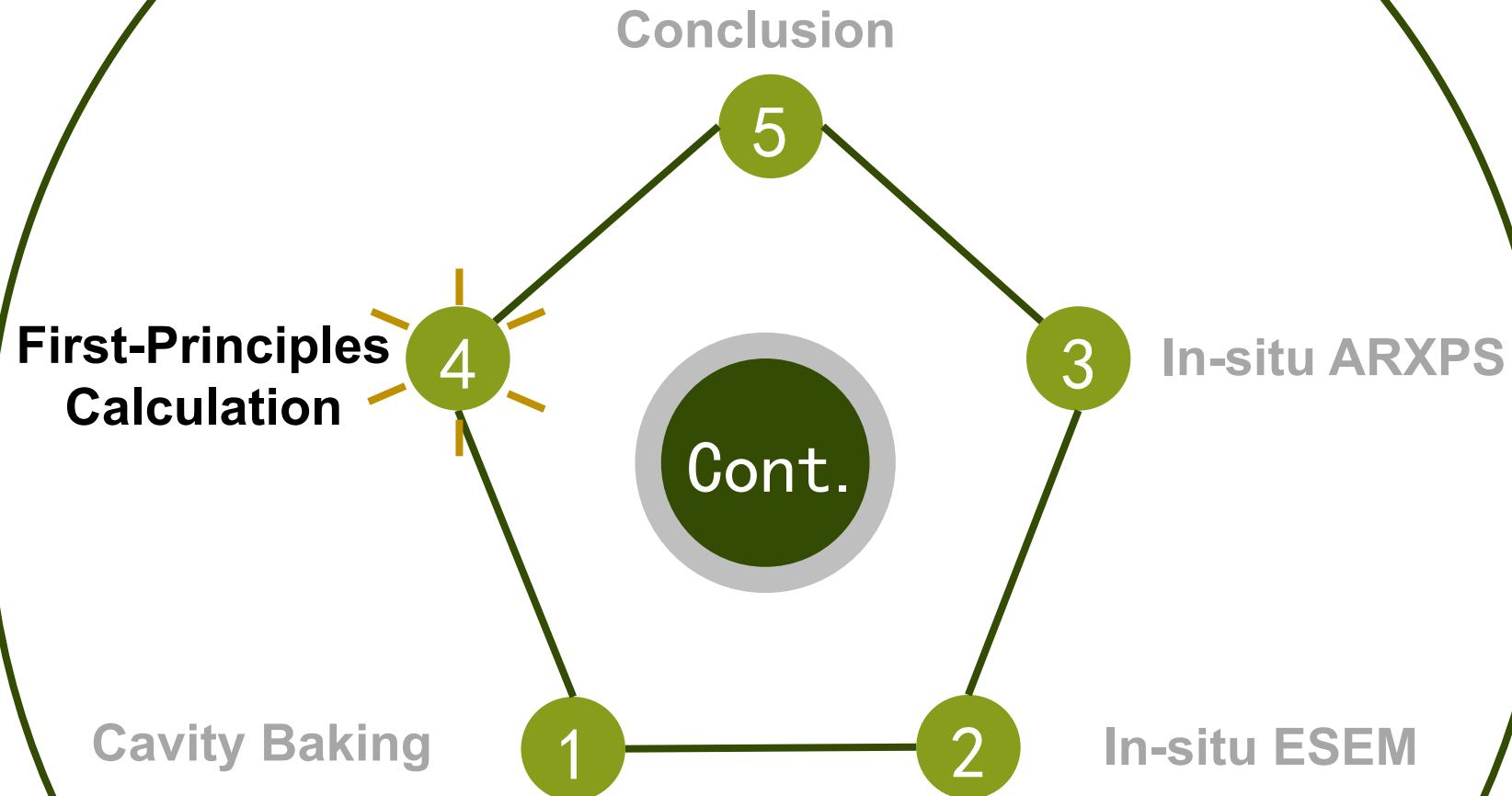


Before and after baking



- C: C, NbC, NbC₂
- O: O, Nb₂O₅, NbO₂, NbO
- H: H, NbH
- Fine grain: C→, O→, H→
- Large Grain: C↓, O→, H↑

45



4.1

Interaction among interstitial atoms



H spatial distribution
WEPWB084



47

Interaction among interstitial atoms



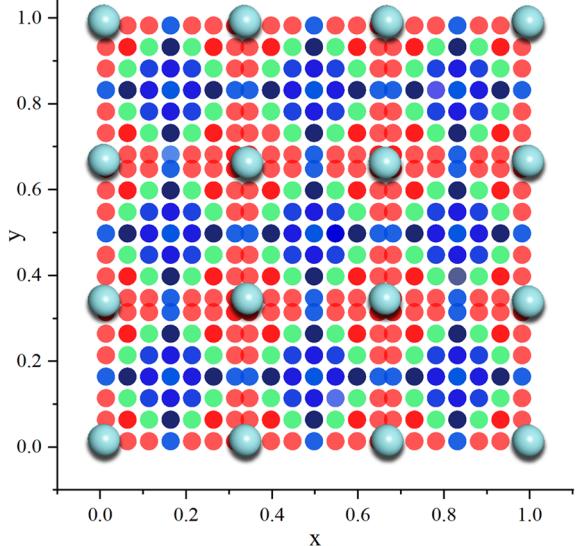
H spatial distribution
WEPWB084



- First principles calculation & Density Function Theory

Interaction among Nb_xB_yH_z atoms

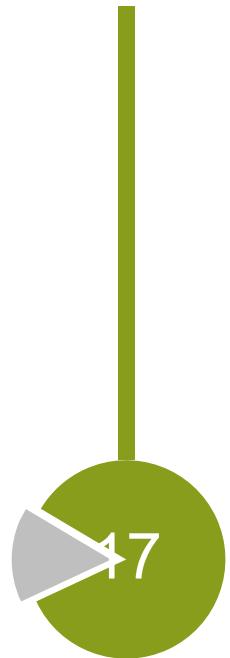
(a) Nb_xB_yH_z atoms



A H spatial distribution
WEPWB084

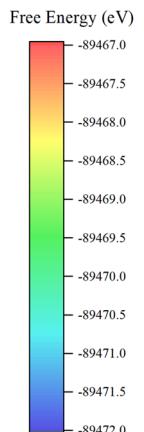
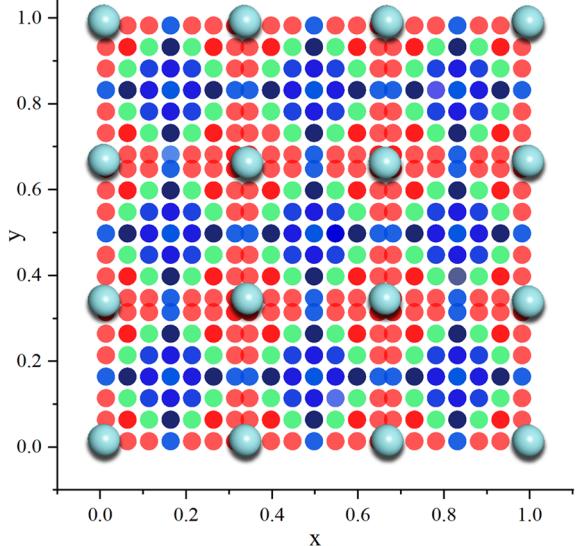


- First principles calculation & Density Function Theory



Interaction among Nb, C, O, N, H

(a) Nb_{1-x}C_xO_{1-y}N_yS



A H spatial distribution
WEPWB084



- First principles calculation & Density Function Theory

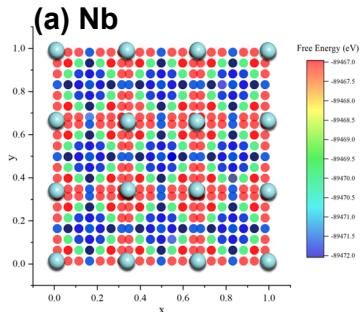
Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

17

Interaction among interstitial atoms



H spatial distribution
WEPWB084



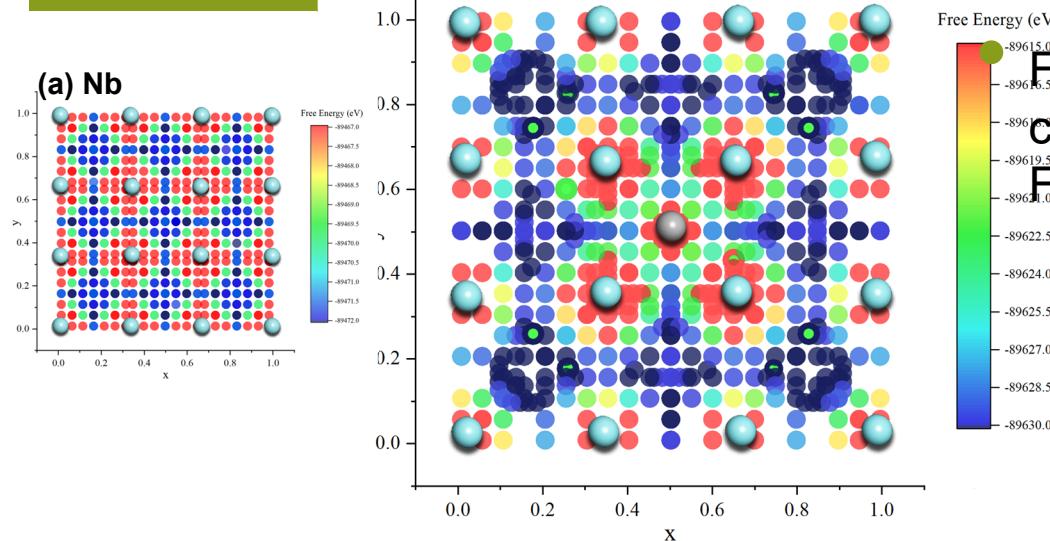
- First principles calculation & Density Function Theory

Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

4.1

Interaction among interstitial atoms

AH spatial distribution
WEPWB084



First principles
calculation & Density
Function Theory

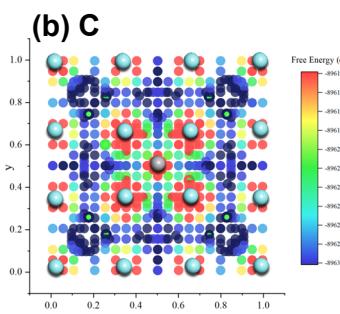
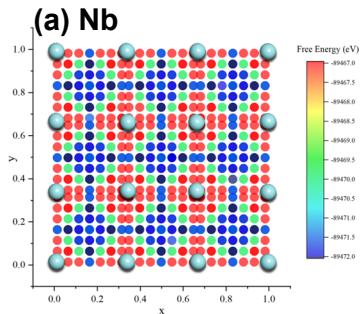
Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

47

Interaction among interstitial atoms



H spatial distribution
WEPWB084



- First principles calculation & Density Function Theory

Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

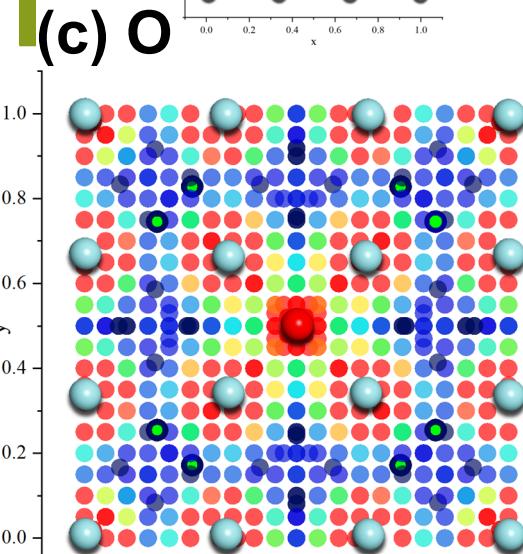
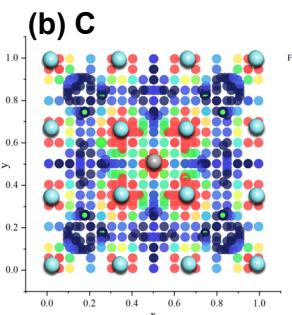
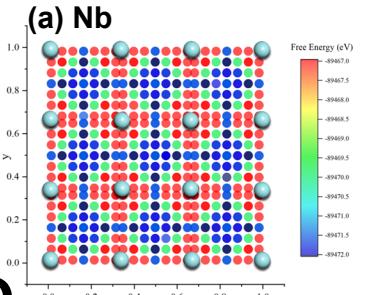
Interaction among interstitial atoms



H spatial distribution
WEPWB084



- First principles calculation & Density Function Theory

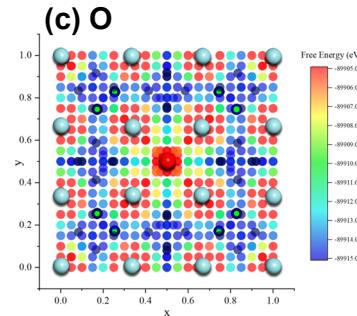
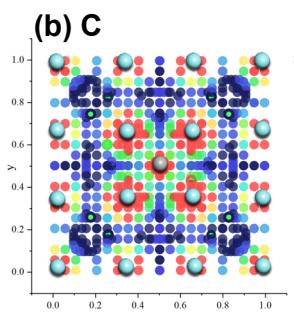
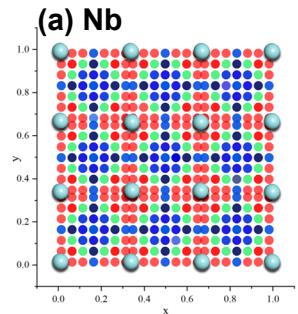


Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

Interaction among interstitial atoms



H spatial distribution
WEPWB084



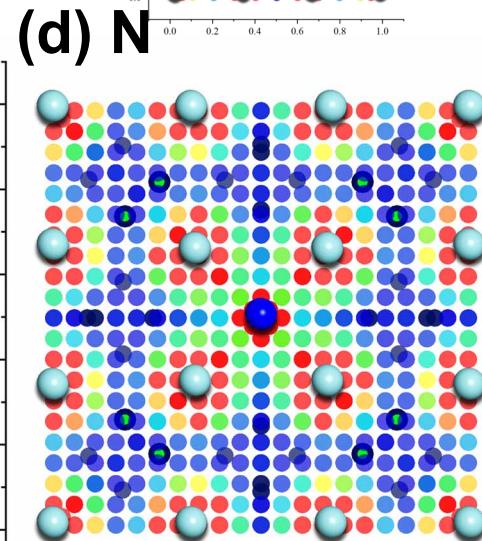
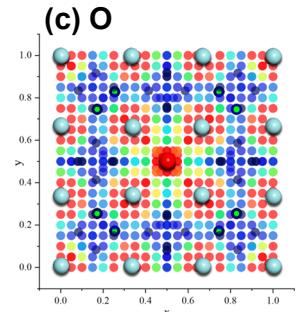
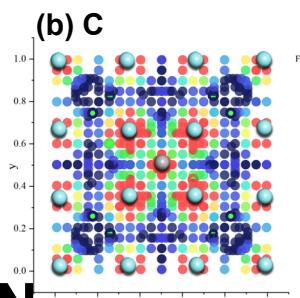
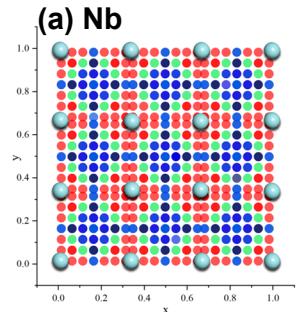
- First principles calculation & Density Function Theory

Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

Interaction among interstitial atoms



H spatial distribution
WEPWB084



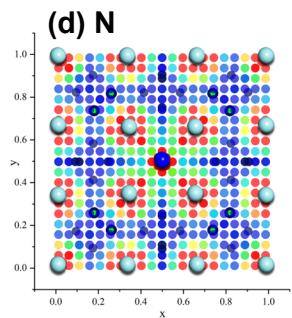
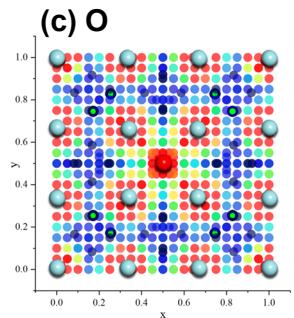
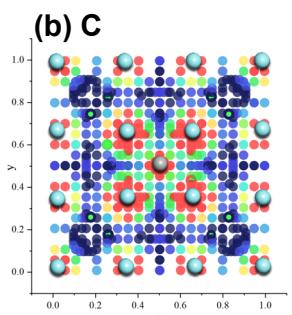
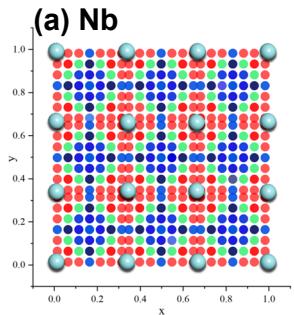
- First principles calculation & Density Function Theory

Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

Interaction among interstitial atoms



H spatial distribution
WEPWB084



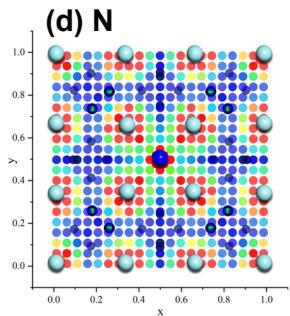
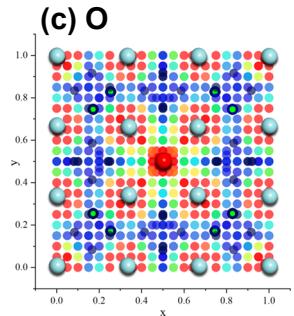
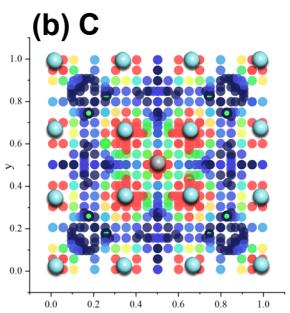
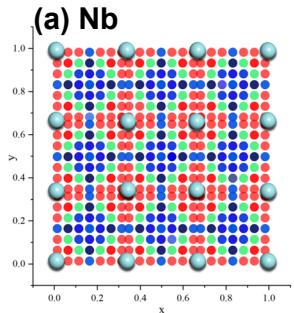
- First principles calculation & Density Function Theory

Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

Interaction among interstitial atoms



H spatial distribution
WEPWB084



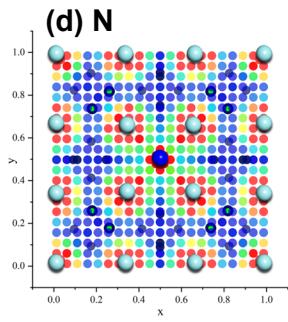
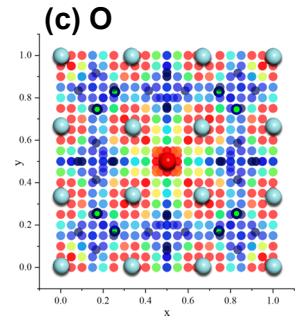
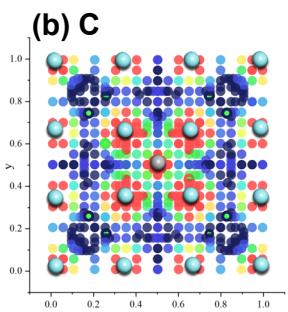
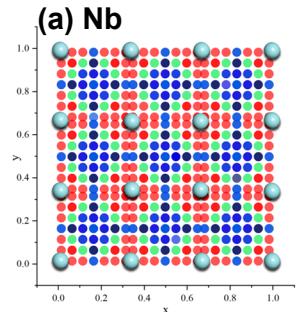
- First principles calculation & Density Function Theory
- Most stable positions: H-Tetrahedral sites, C/N/O-Octahedral sites

Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

Interaction among interstitial atoms



H spatial distribution
WEPWB084



- First principles calculation & Density Function Theory
- Most stable positions: H-Tetrahedral sites, C/N/O-Octahedral sites
- C/N/O reduce the most stable sites of H, so as to diffusion routes of H

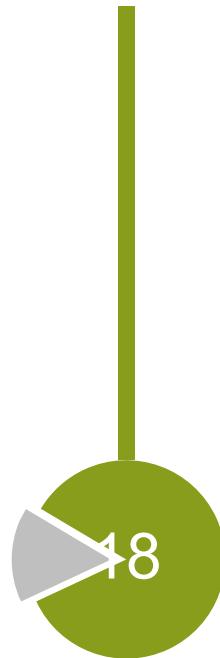
Light blue 3D sphere: Nb
Gray 3D sphere: C
Red 3D sphere: O
Dark blue 3D sphere: N
Colored 2D circles: H

4.1

Interaction among interstitial atoms



DOS distribution
WEPWB084



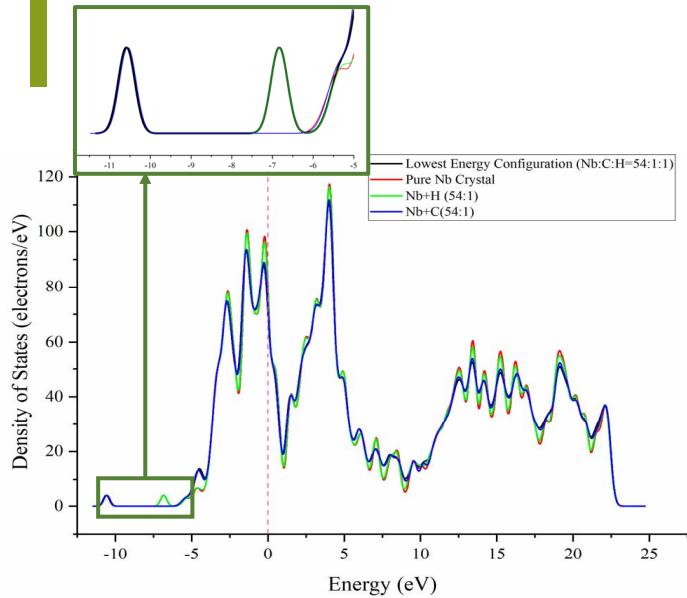
4

(a) Nb_{1-x}C_xH

Interaction among interstitial atoms



DOS distribution
WEPWB084



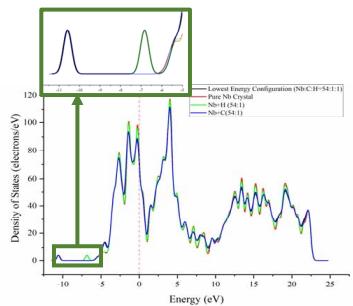
18

Interaction among interstitial atoms

B DOS distribution
WEPWB084



(a) Nb-C-H



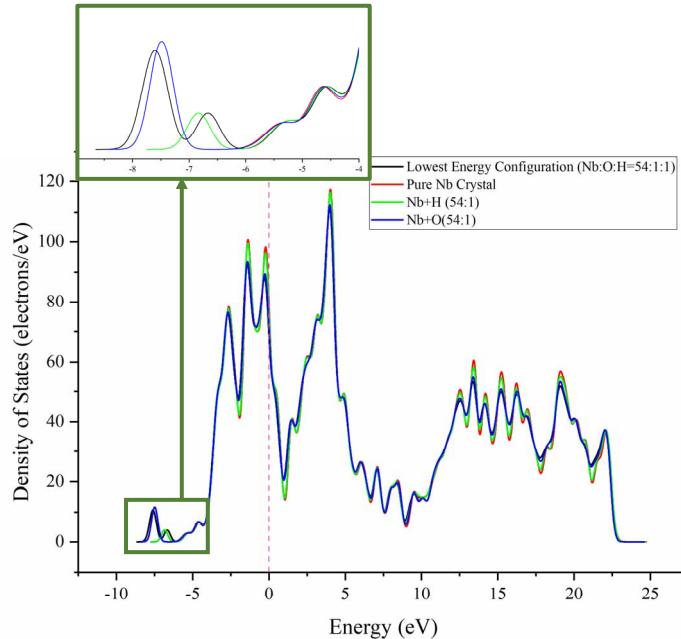
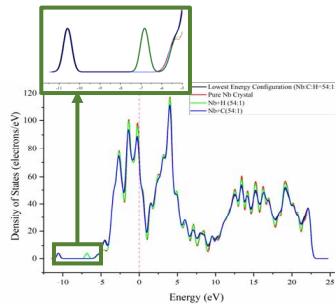
Interaction among interstitial atoms ($\text{Nb}+\text{H}$)₅₄-O-H



DOS distribution
WEPWB084



(a) Nb-C-H

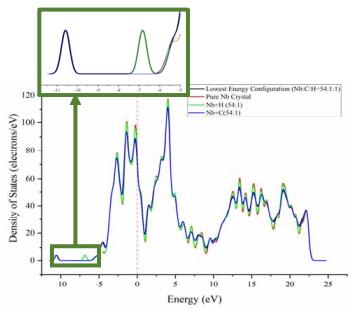


Interaction among interstitial atoms

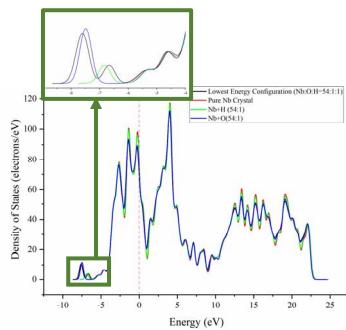
B DOS distribution
WEPWB084



(a) Nb-C-H



(b) Nb-O-H



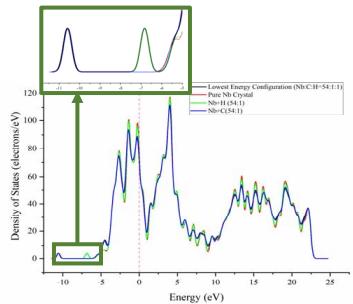
Interaction among interstitial atoms



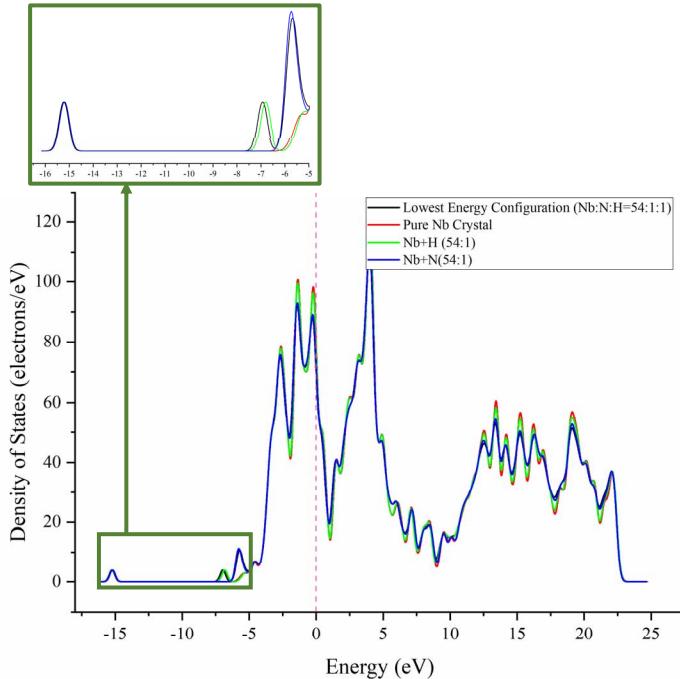
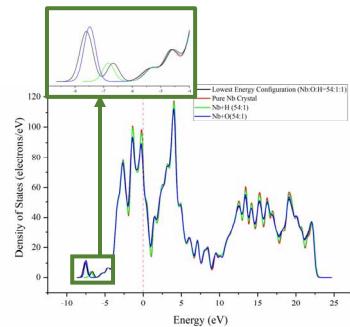
DOS distribution
with Nb:N=8:4



(a) Nb-C-H



(b) Nb-O-H



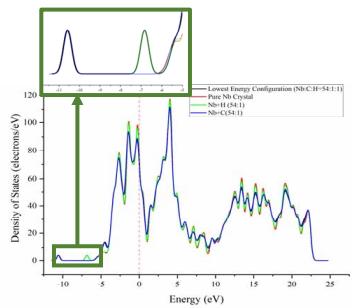
Interaction among interstitial atoms



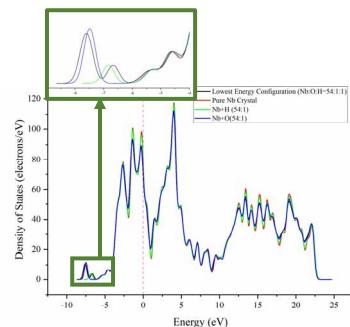
DOS distribution
WEPWB084



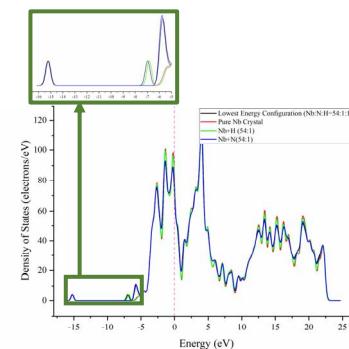
(a) Nb-C-H



(b) Nb-O-H



(c) Nb-N-H



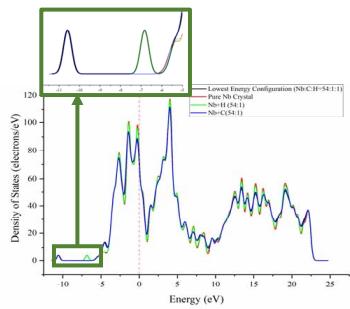
Interaction among interstitial atoms



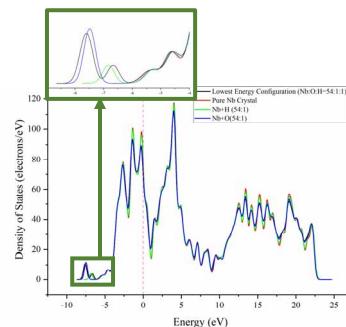
DOS distribution
WEPWB084



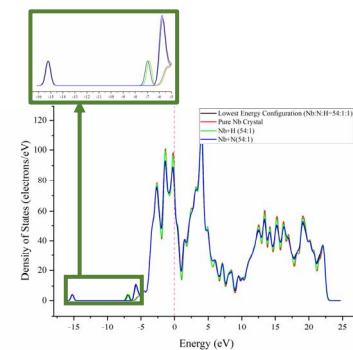
(a) Nb-C-H



(b) Nb-O-H



(c) Nb-N-H

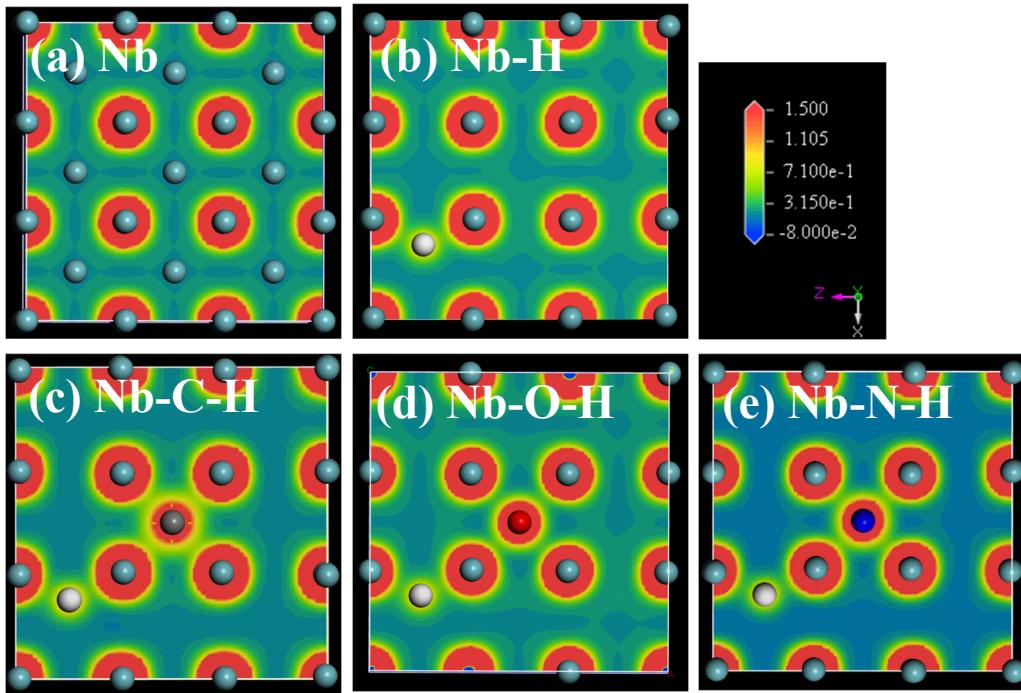


- Nb-C, Nb-O, Nb-N, Nb-H Chemical Bonds
- C/N/O cannot destroy but slightly move Nb-H bond
- C/N/O/H can only slightly change DOS of Nb

Interaction among interstitial atoms



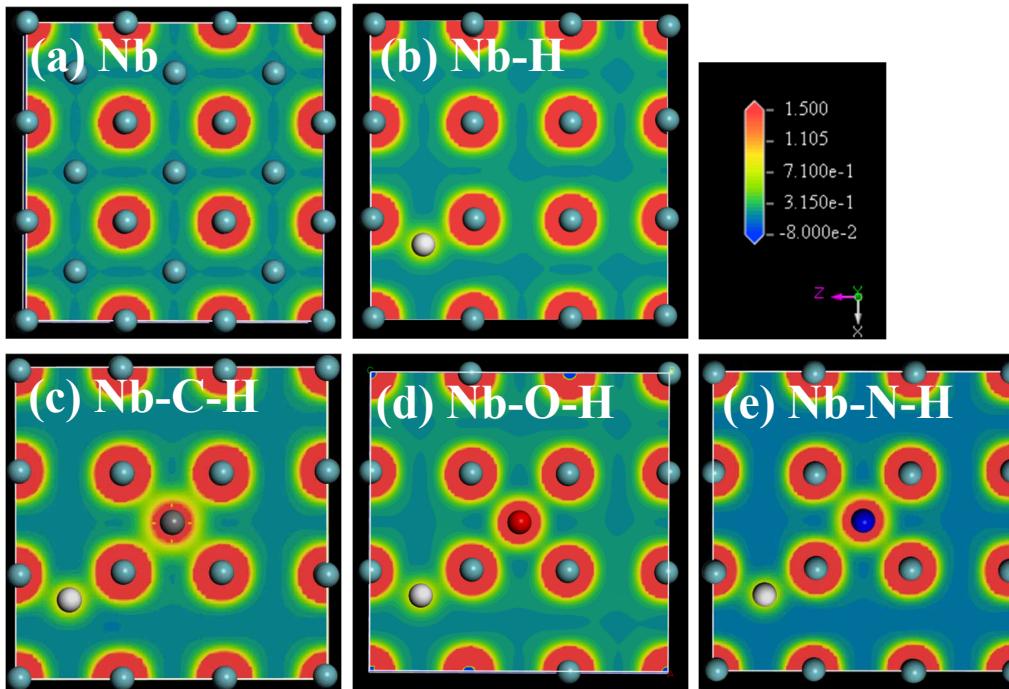
Electron density
WEPWB084



Interaction among interstitial atoms



Electron density
WEPWB084



- C/N/O/H can attract free electron of Nb
- C/N/O have stronger attractive effects of electron than H
- C have similar interaction with H as N and O in the aspects of stable sites of H, Nb DOS and system electron density

4.2

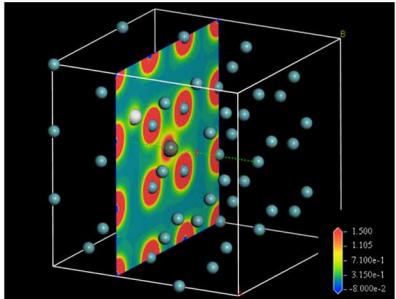
Interaction between vacancy and C/N/O/H



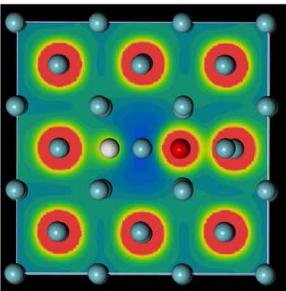
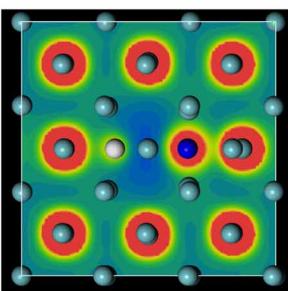
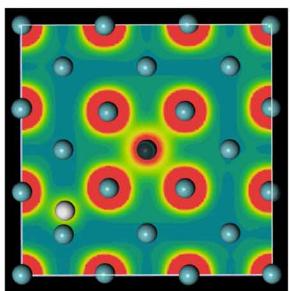
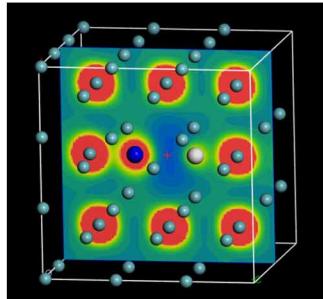
Electron density
WEPWB084



Lowest Energy Structure
Nb-V-C-H



Lowest Energy Structure
Nb-V-N/O-H



Electron density Nb-V-C-H Electron density Nb-V-N-H Electron density Nb-V-O-H

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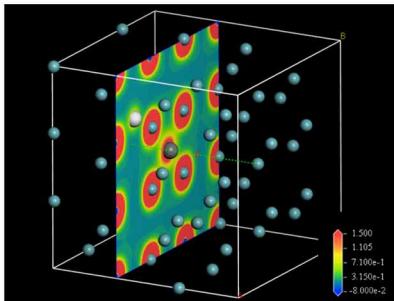
Interaction between vacancy and C/N/O/H



Electron density
WEPWB084

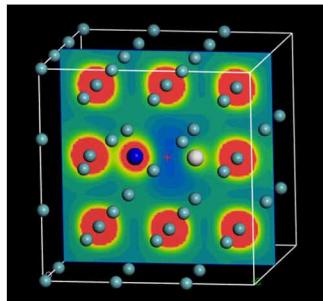


Lowest Energy Structure
Nb-V-C-H

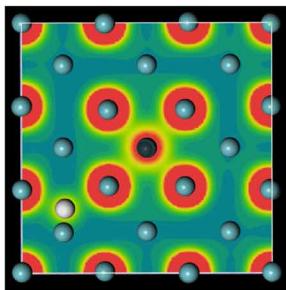


(a)

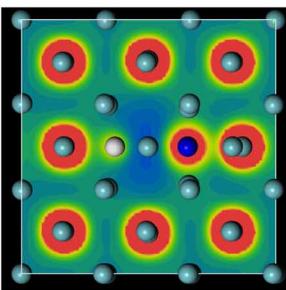
Lowest Energy Structure
Nb-V-N/O-H



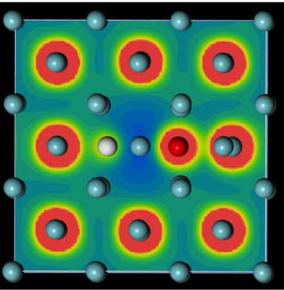
(b)



(c)



(d)



(e)

Electron density Nb-V-C-H

Electron density Nb-V-N-H

Electron density Nb-V-O-H

- In the lowest energy structure Nb-V-C-H, H locates at a tetrahedral site near the vacancy, similarly to the situation without vacancy.
- In the lowest energy structure Nb-V-N-H and Nb-V-O-H, H locates at the octahedral site near the vacancy

Interaction between vacancy and C/N/O/H

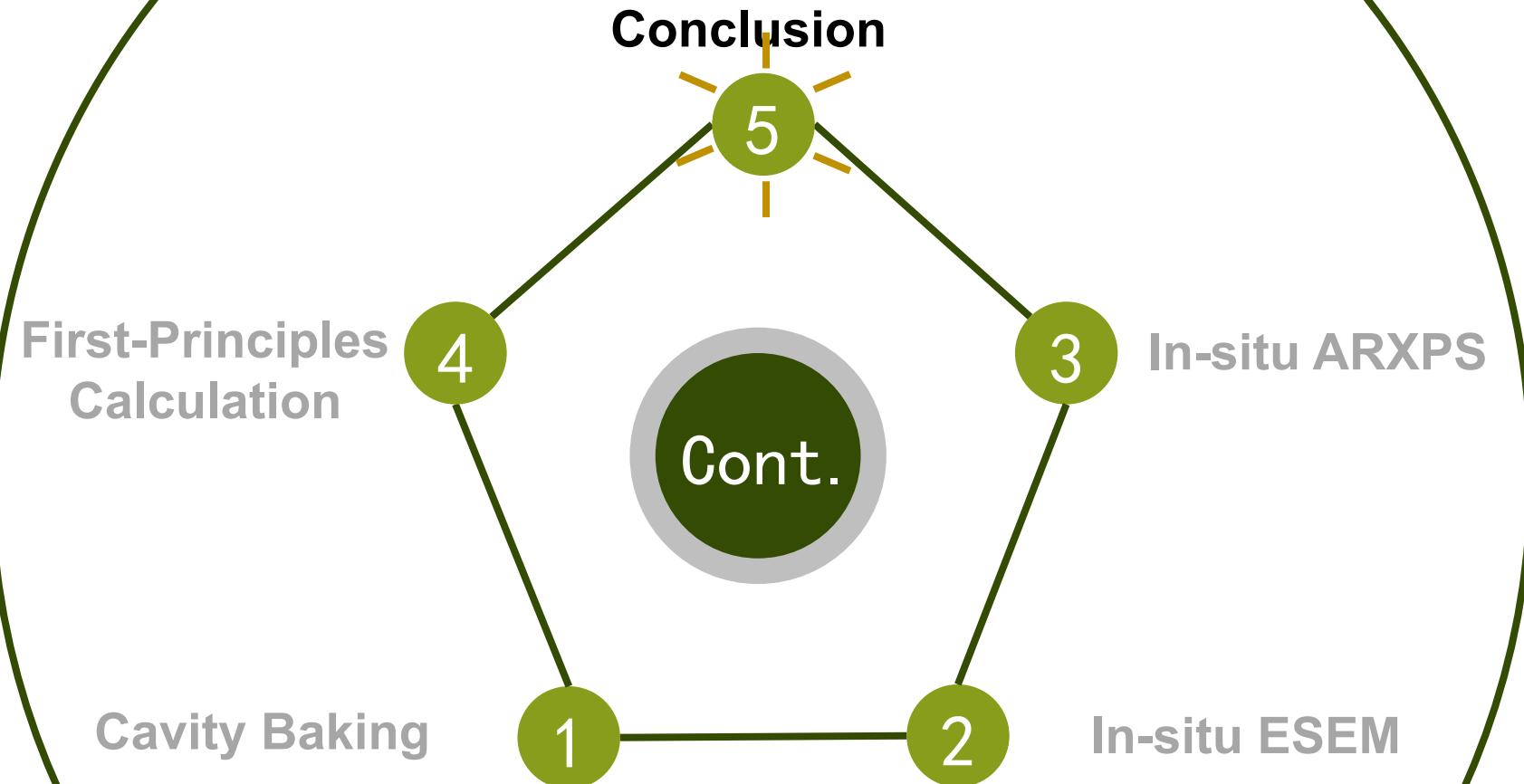


Peak searching of DOS
WEPWB084



System	Element	Peak 1		Peak 2		Peak 3		Peak 4					
		Center (eV)	Area(e)	Center (eV)	Area(e)	Center (eV)	Area(e)	Center (eV)	Area(e)				
C+H+ V+Nb	C	-10.892	1.383	-7.536	1.120	-4.022	2.890	?	?				
	H	-	-										
	Nb	10.892	0.513										
N+H+ V+Nb	N	-14.678	1.616	-6.081	0.893	-5.334	2.463	-4.671	3.732				
	H	14.678	0.415					-4.524	1.052				
	Nb												
O+H+ V+Nb	O	19.98156	1.75907	-6.72451	3.74937	-6.44043	0.42456	-5.66185	2.35442				
	H							-5.61976	1.52196				
	Nb												

Note: '?' means that the peaks are so close to the Fermi surface that one cannot deduct the background signal properly.



5.1

Summary



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Summary



400°C can decompose
Nb-O and form Nb-C
compounds, maybe C-
doping effect

Summary



800°C decompose Nb-O and Nb-C, only pure Nb left



400°C can decompose Nb-O and form Nb-C compounds, maybe C-doping effect

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The loss of protection layer leads to hydrogen reabsorption

Summary



800°C decompose Nb-O and Nb-C, only pure Nb left



C/N/O have similar effect in suppress the diffusion of H by reducing its lowest energy position

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Summary



800°C decompose Nb-O and Nb-C, only pure Nb left



C/N/O have similar effect in suppress the diffusion of H by reducing its lowest energy position

400°C can decompose Nb-O and form Nb-C compounds, maybe C-doping effect

C/N/O/H can only slightly impact the DOS of Nb with correspondingly chemical bonds

The loss of protection layer leads to hydrogen reabsorption

5.2

Future work



A ➤ B

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Experiment

- In-situ ARPES experiment on superconducting niobium: observe the baking temperature responses of the electron pair behavior in momentum space
- Medium temperature baking of Niobium cavity with more accurate temperature controlling and pre-oxidization (**WEPWB045**)





Experiment

- In-situ ARPES experiment on superconducting niobium: observe the baking temperature responses of the electron pair behavior in momentum space
- Medium temperature baking of Niobium cavity with more accurate temperature controlling and pre-oxidization (**WEPWB045**)



Simulation

- Interaction among vacancy, dislocation and grain boundaries
- Temperature responses of the interaction between interstitial C/N/O and H
- Temperature responses of the interaction between vacancy and H
- Nb-H precipitation, cooling



FOREVER MEMORY



Thanks for your attention

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